

**Enge Wang**

**Institute of Physics, Chinese Academy of Sciences**





Beijing  
Airport

location



China



BEIJING

Harbin

Shenyang

Ürümqi

Lanzhou

Xi'an

Zhengzhou

Shanghai

Wuhan

Lhasa

Chongqing

Guangzhou

Kunming

Hongkong

Taipei

Haikou



清 华 大 学

北 京 大 学

Chinese Academy of Sciences

IPCAS









# History of IoP/CAS



**National Research Institute of Physics (1928.3-1950.5)**



**The Institute of Physics, National Academy of Peking (1929.9-1950.5)**

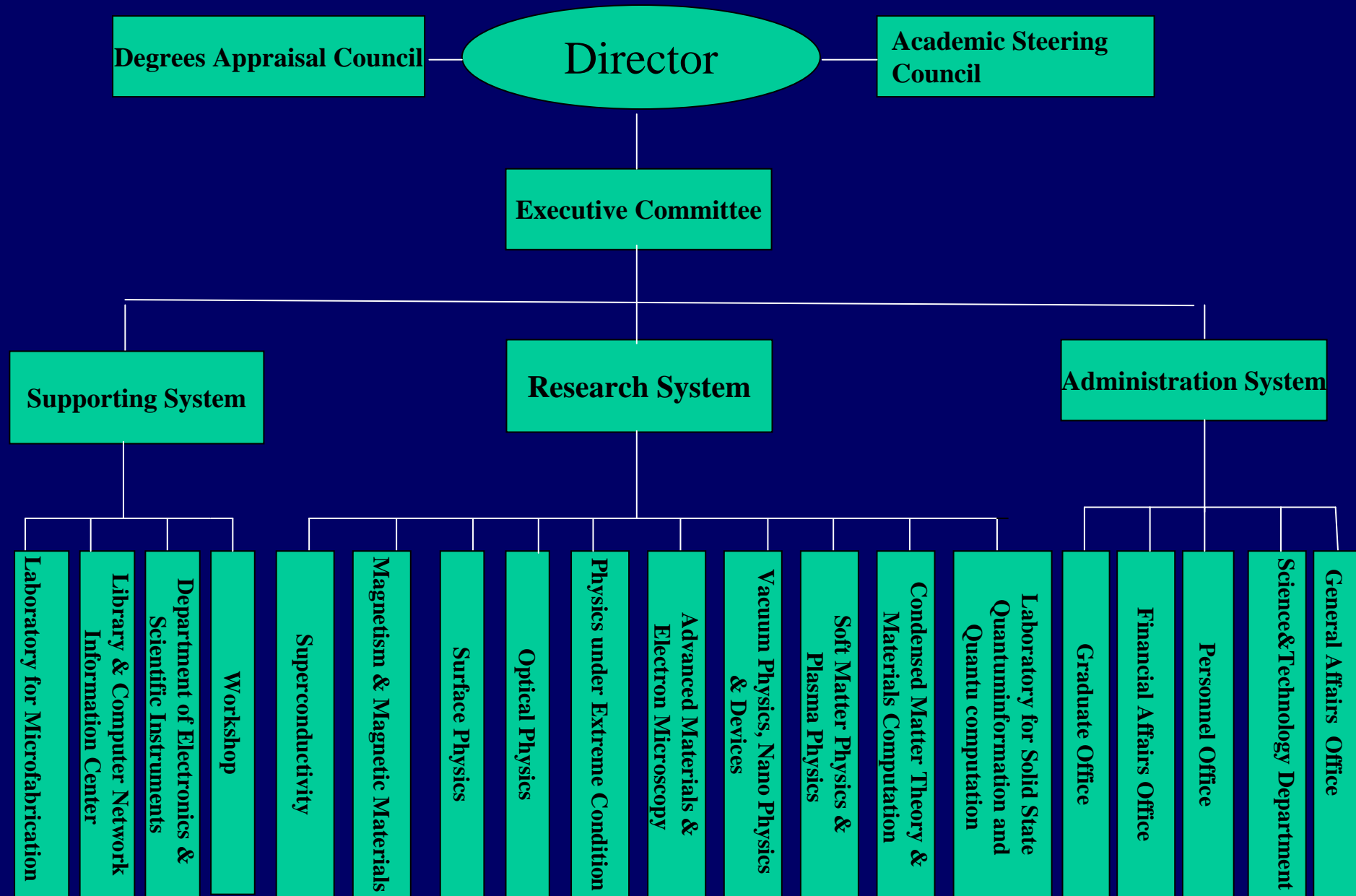
**The Institute of Applied Physics  
CAS ( 1950 )**



**The Institute of Physics, CAS ( 1958 )**



# Organization





# Staffing

Research Staff: 183

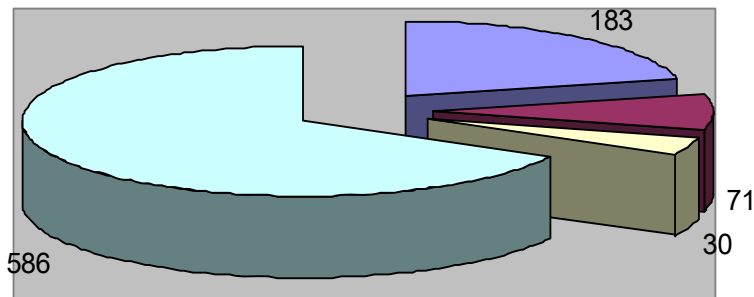
Technical Support Staff: 71

Students: 586

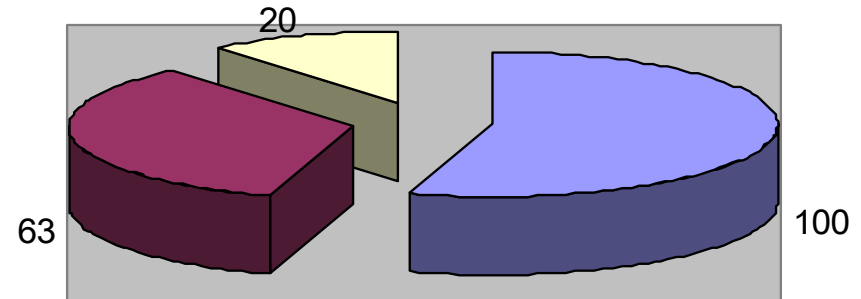
Administrative Staff: 30

Total number: 870

Staff and Student



Research Staff



*(according to the Statistic by the end of 2004)*



# Physical Awards by TWAS :

**Z. X. Zhao**

**K. H. Kuo**

**H. F. Fan**



**15 Academicians**  
**(59 Academicians in history)**



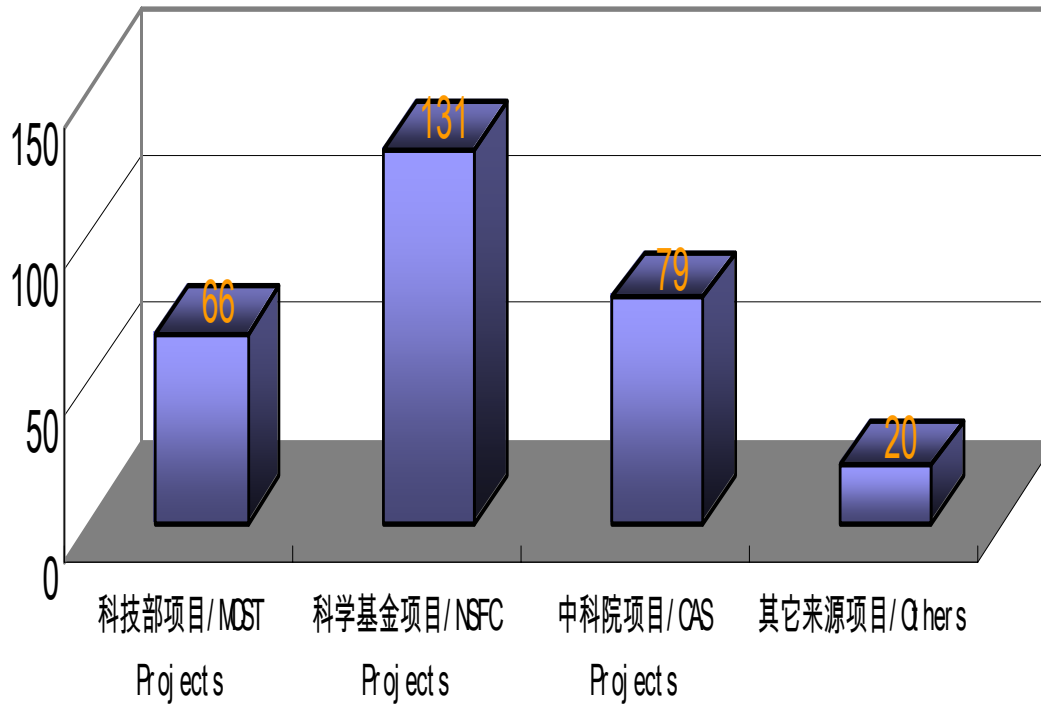




**Prof. Fang-hua Li at the prize-awarding ceremony**

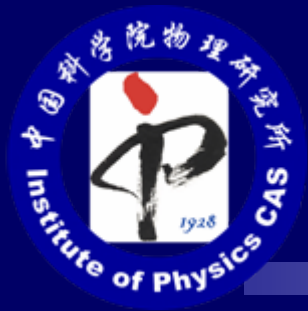


# General View on-going Projects



**Budget: 1/3 from CAS, 2/3 from competitive funds**





# Research Areas and Highlights

---

## Main Achievements:

- \* High  $T_c$  oxide superconductors at liquid nitrogen temperatures
- \* Nd-Fe-B permanent magnetic alloys using low purity materials
- \* Synthesis of nonlinear crystals
- \* Study on symmetry and property of quasicrystals





## Main Achievements:

- \* High  $T_c$  oxide superconductors at liquid nitrogen temperatures
- \* Nd-Fe-B permanent magnetic alloys using low purity materials
- \* Synthesis of nonlinear crystals
- \* Study on symmetry and property of quasicrystals



# San Huan Company



以稀土和非晶态合金基本磁性理论为基础，研制成功钕铁硼磁钢。

钕铁硼  
界同行

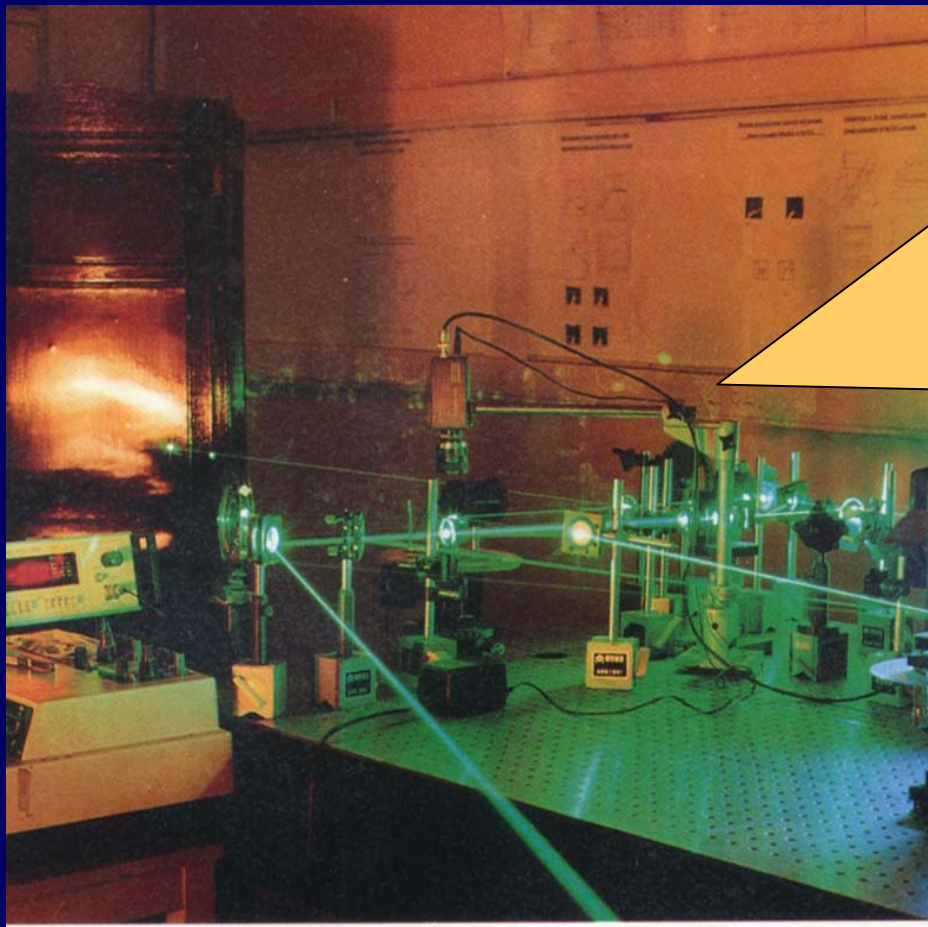




## Main Achievements:

- \* High  $T_c$  oxide superconductors at liquid nitrogen temperatures
- \* Nd-Fe-B permanent magnetic alloys using low purity materials
- \* **Synthesis of nonlinear crystals**
- \* Study on symmetry and property of quasicrystals





Observation of a new mechanism generating self-pumped phase-conjugate reflection in photorefractive crystals





## Main Achievements:

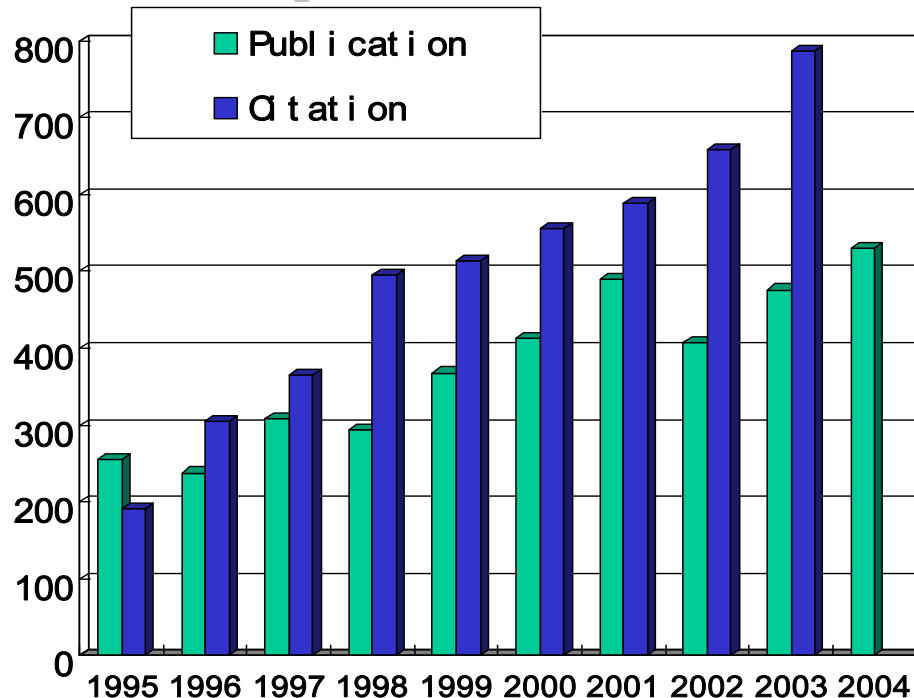
- \* High  $T_c$  oxide superconductors at liquid nitrogen temperatures
- \* Nd-Fe-B permanent magnetic alloys using low purity materials
- \* Synthesis of nonlinear crystals
- \* Study on symmetry and property of quasicrystals



# General View of Publication

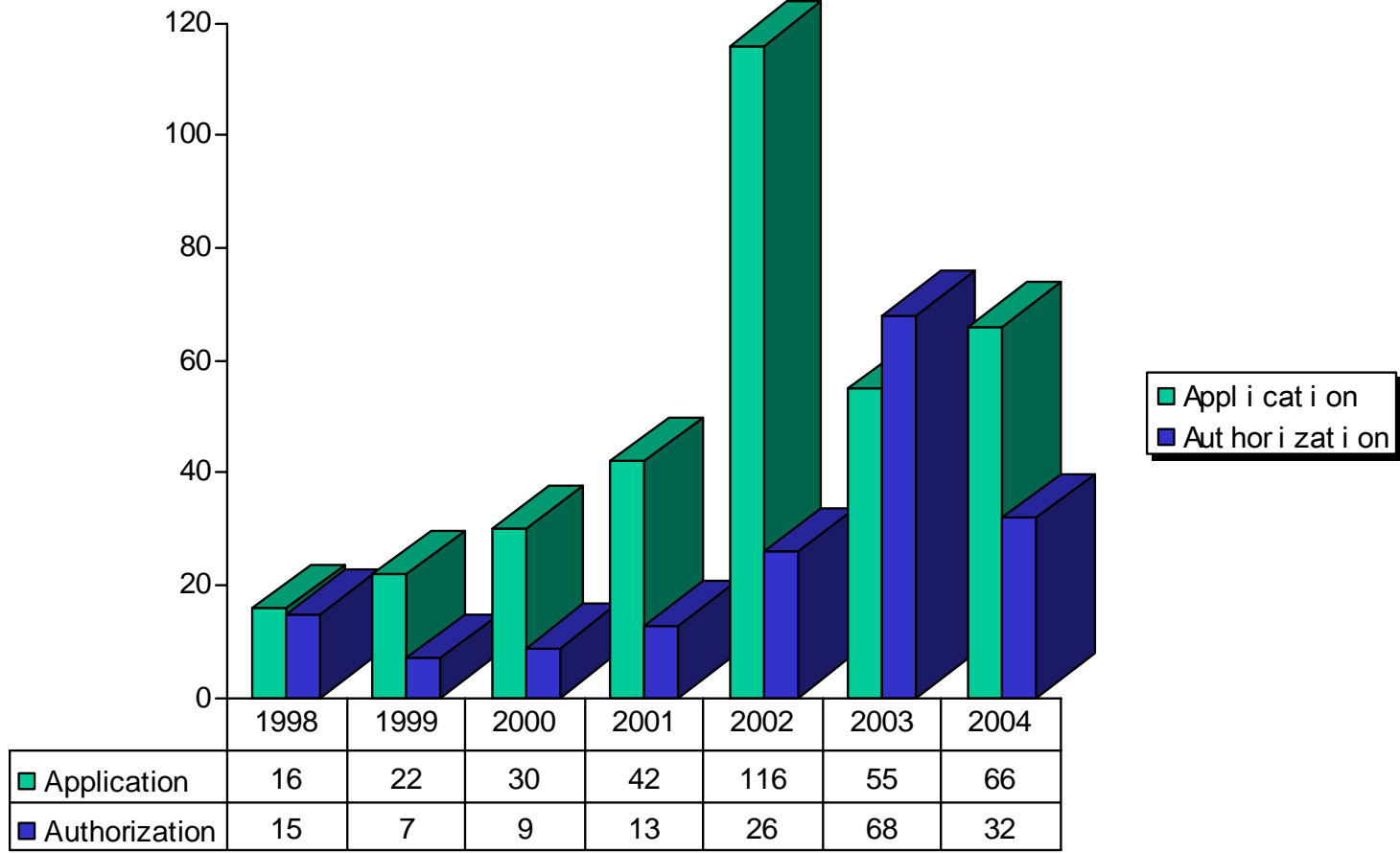
| Year   | 1997 | 1998 | 1999 | 2000 | 2001 | 2002 | 2003 | 2004 |
|--------|------|------|------|------|------|------|------|------|
| Papers | 293  | 294  | 337  | 431  | 489  | 407  | 476  | 530  |

**The numbers of publication and citation have been ranked at the top in China for more than ten years in succession.**



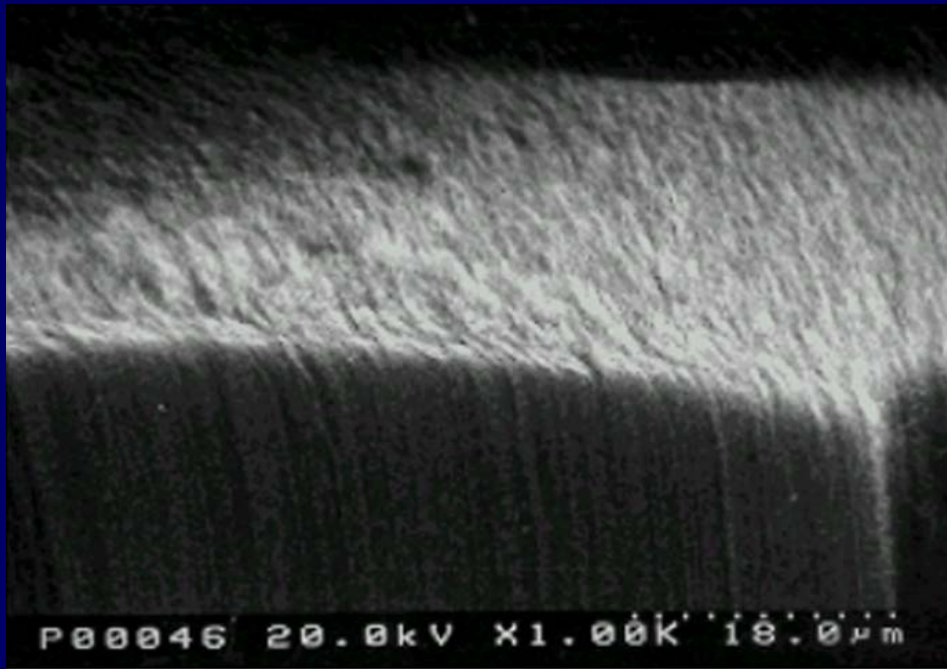
**Each year:**  
**~ 2 -3 in Nature or Science;**  
**~ 20 in PRL and JACS.**

# Patents Application and Authorization

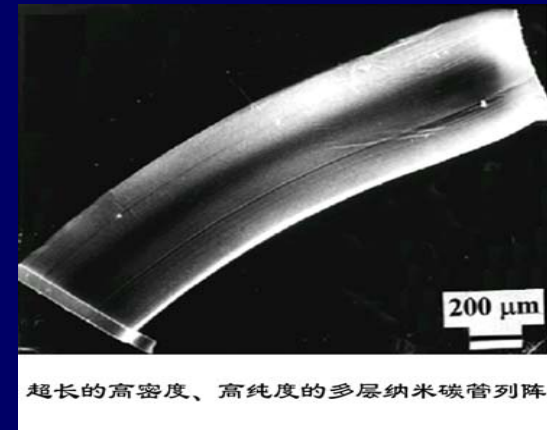




# Synthesis of aligned nanotubes array



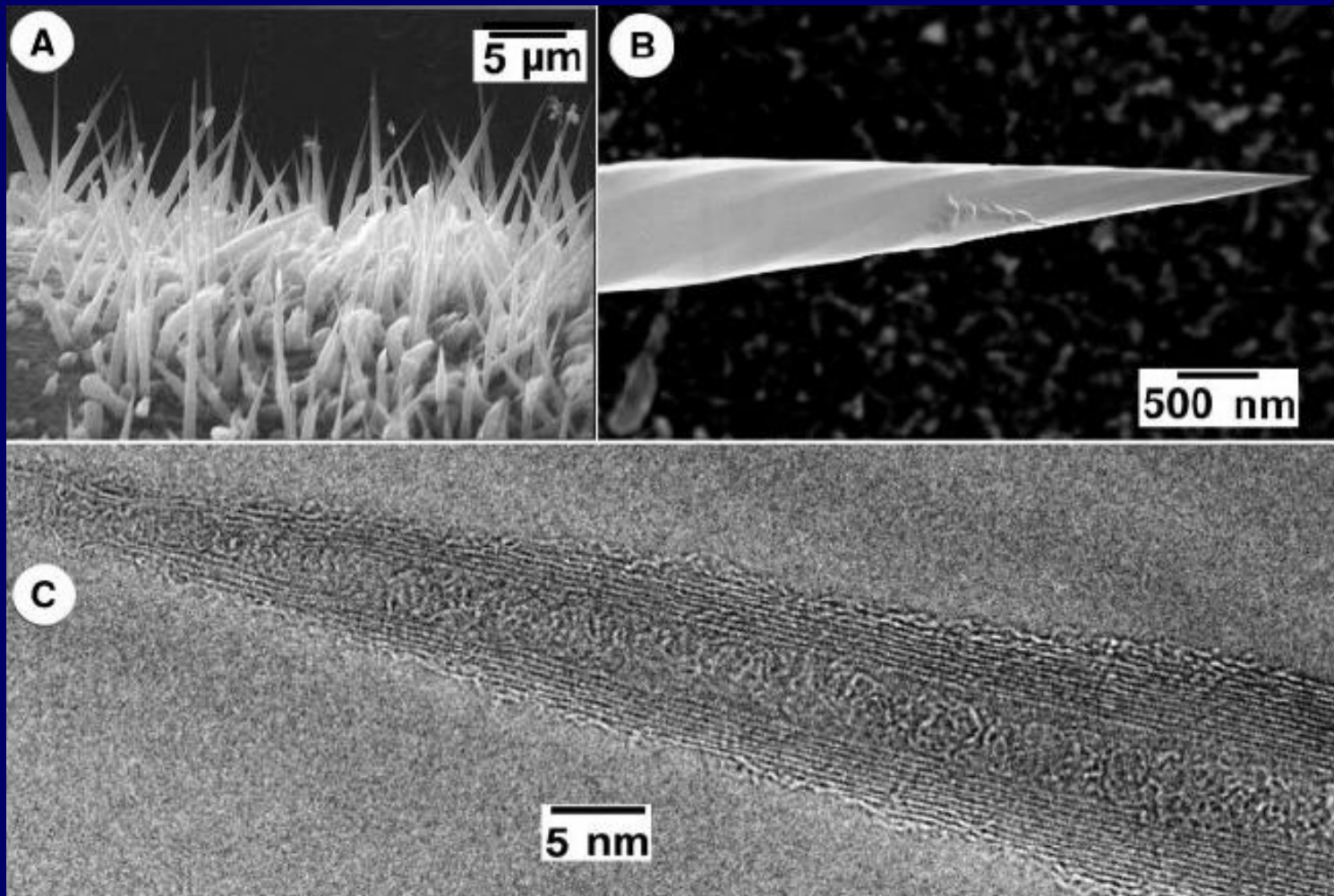
从衬底上取下的纳米碳管阵列底部的 SEM 像



超长的高密度、高纯度的多层纳米碳管阵列

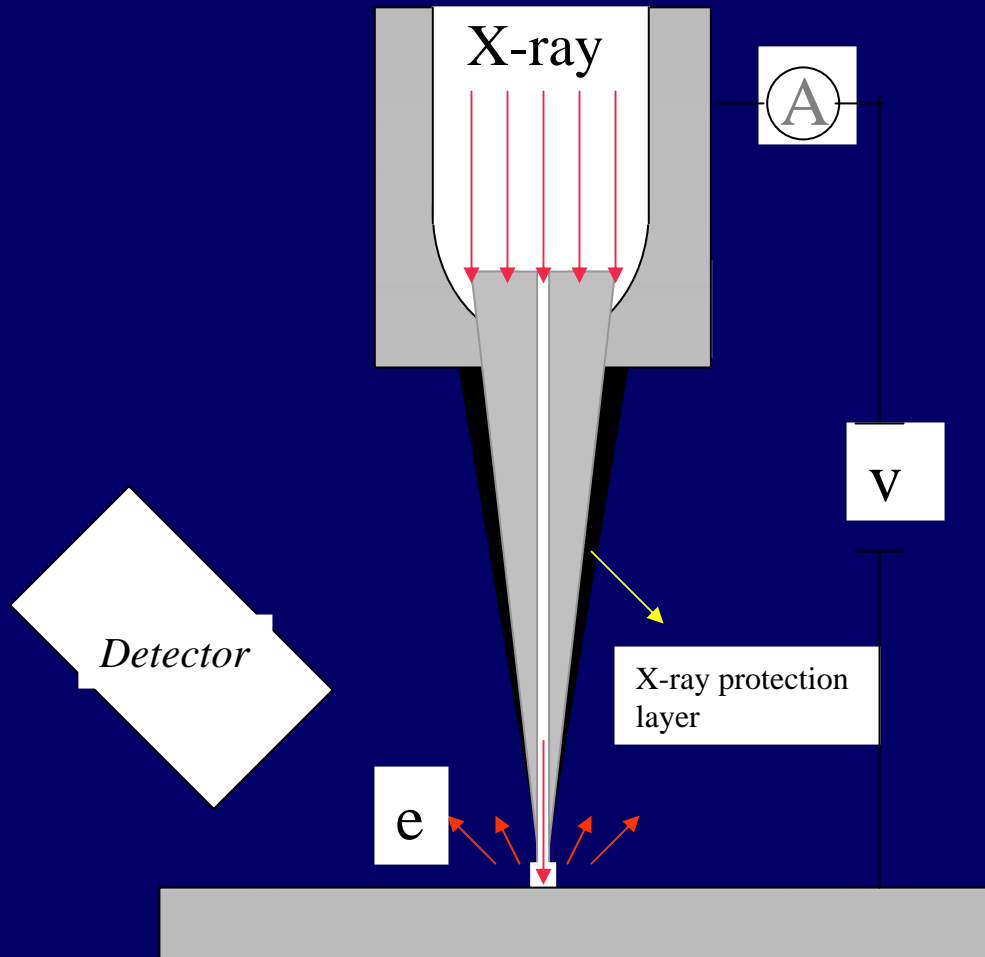
*Nature* 403, 403(2000); *Nature* 394, 631(1998);  
*Science* 274, 1701(1996); *Phys. Rev. Lett.* 84, 2701(2000);

# Tubular Graphite Cones



Science 300, 18 (2003)

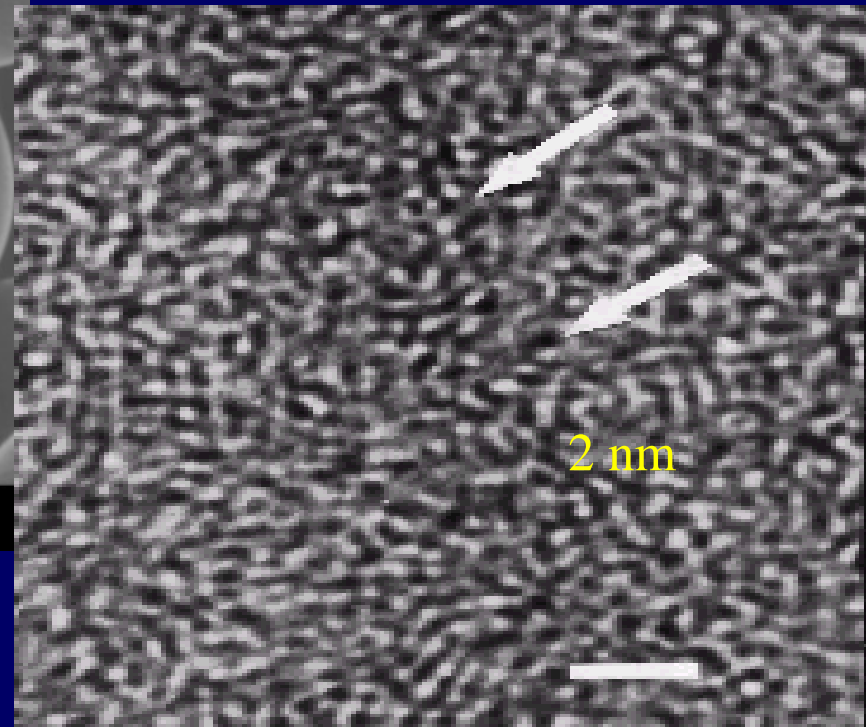
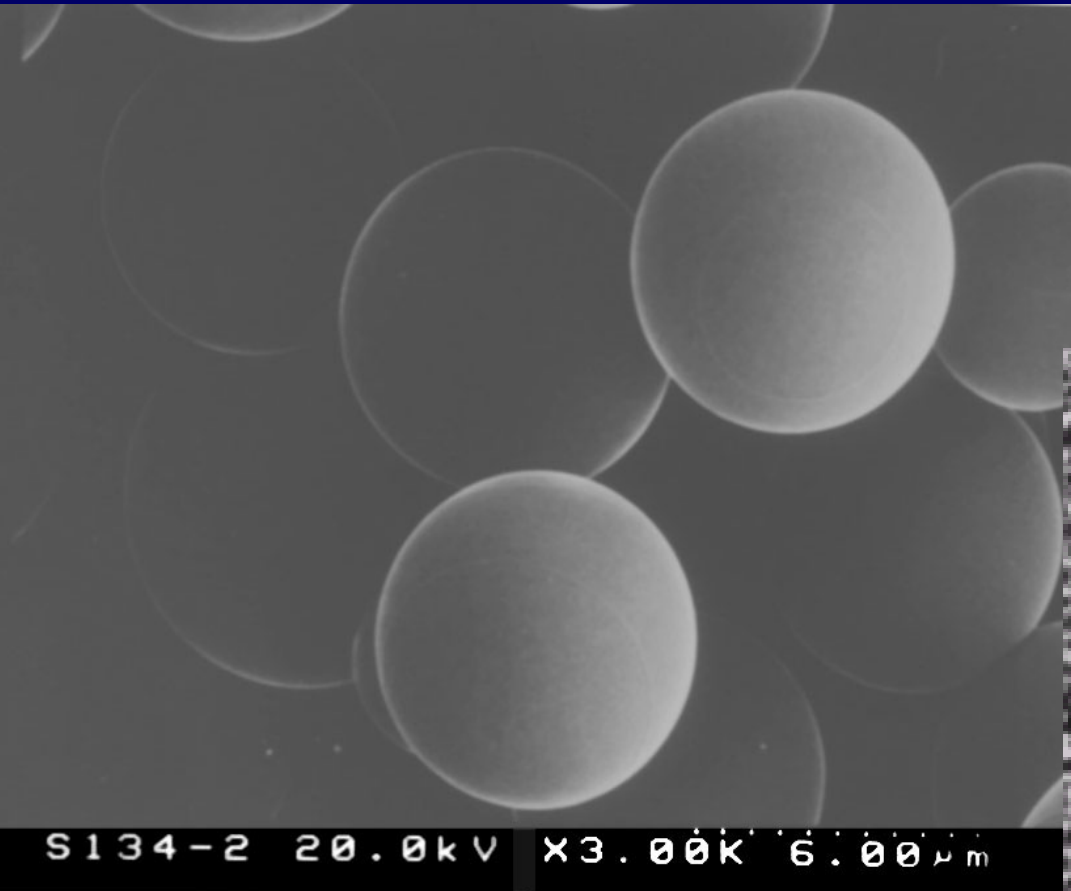
# SPM with composition analysis

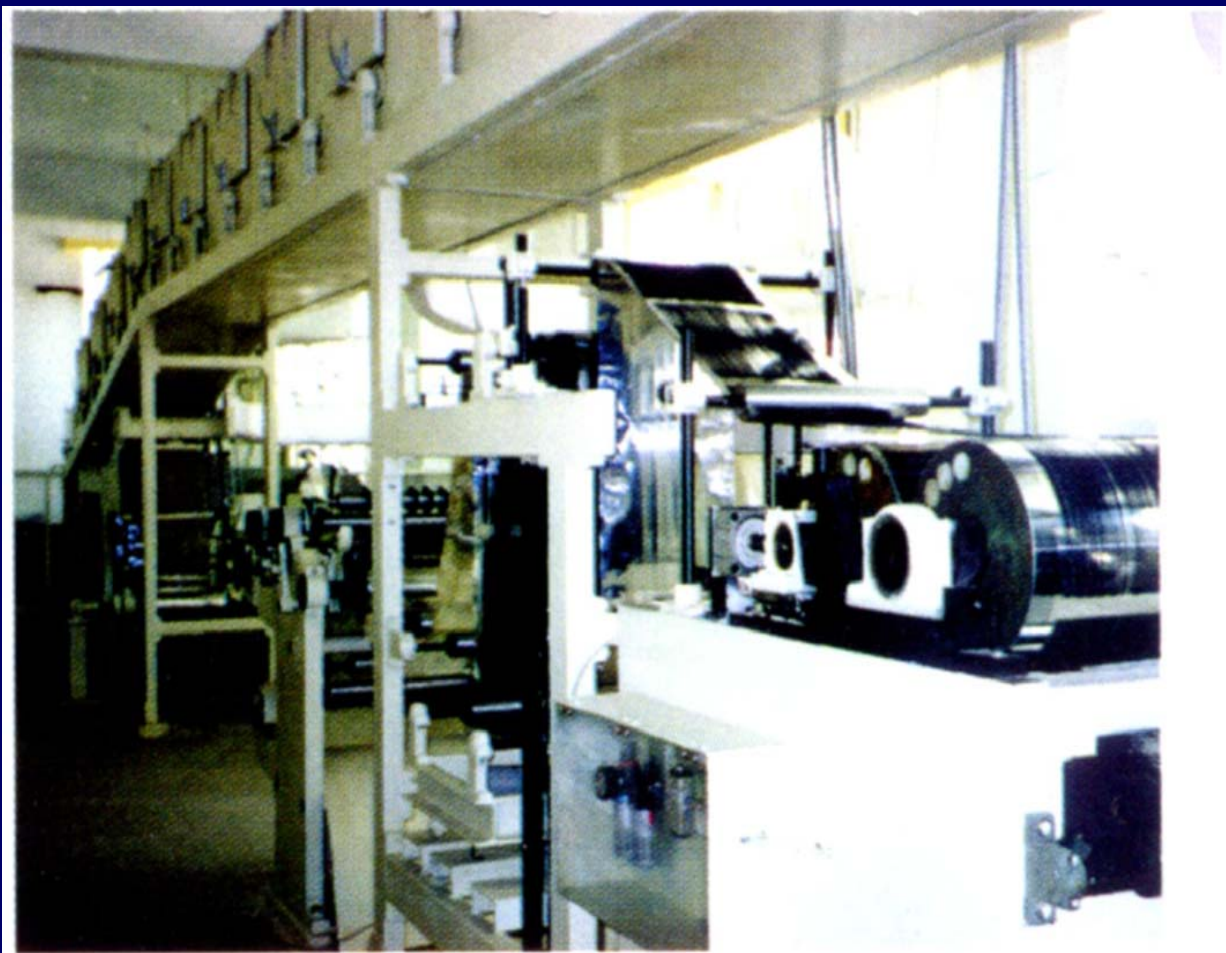


- 1) Hard as carbon nanotube, but more stable in radial direction.
- 2) Atomic resolution image and composition information of single/several atoms.



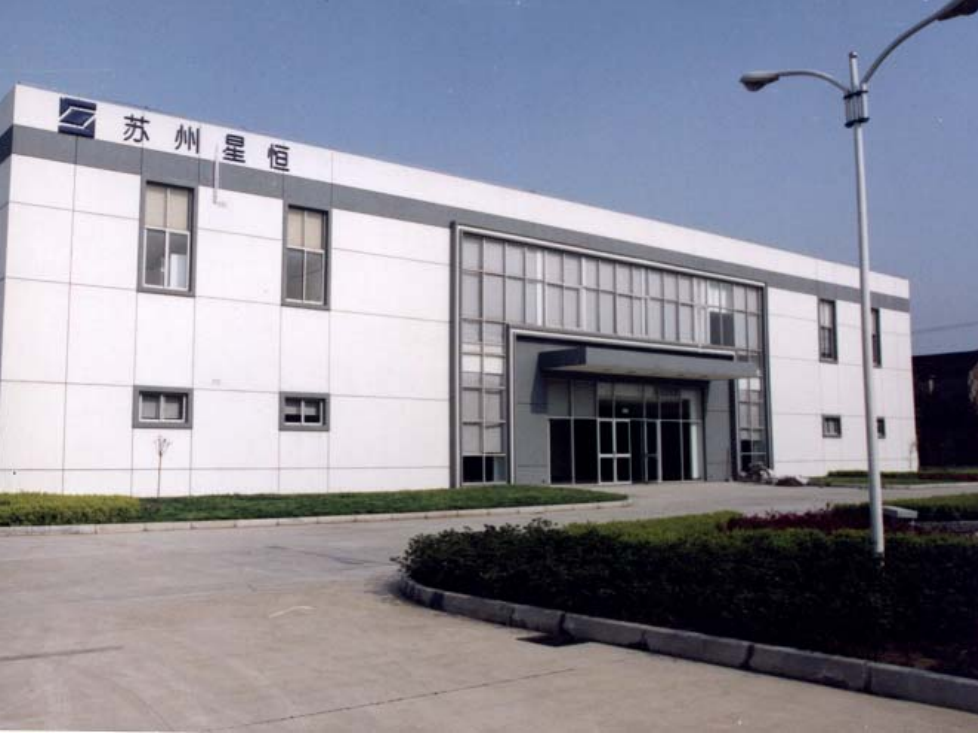
# Hard Carbon Spherules (HCS)





**Beijing Phylion Battery Inc.**



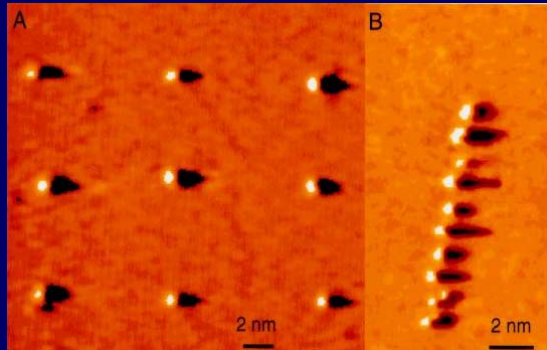


05年上海燃料电池+电池混合汽车示范运行车队和产业化项目  
华普油电混合汽车均采用我们的高功率锂离子电池



# Ultrahigh density information storage

## --- Towards the next generation of CD



Molecular recording on NBMN/pDA thin films, showing the size of the marks to be about 0.8 nm. The minimum distance between two recorded marks is 1.2 nm.

Phys. Rev. Lett. 84, 1780 (2000).

100 years of physics

American Physical Society

member directory  
membership services  
aps units  
meetings  
education/women/minorities  
international affairs  
public affairs  
media relations  
prizes & awards

research journals  
what's new by Bob Park  
phys rev focus  
aps news online  
careers & employment  
fund raising  
century of physics timeline  
physics internet resources  
society & contact info

search | email | mirror

Wednesday, March 22, 2000

Toward the Next Generation CD

Page 1

### Physical Review Focus

Reversible, Nanometer-Scale Conductance Transitions in an Organic Complex  
H. J. Gao, K. Solberg, Z. Q. Xue, H. Y. Chen, S. M. Hou, L. P. Ma, X. W. Pang, S. J. Pang, and S. J. Pennycook  
*Phys. Rev. Lett.* 84, 1780 (21 February 2000)

### Toward the Next Generation CD

16 February 2000

Andrew Gannon

From punch cards to floppy disks to CD-ROMs, data storage devices continue to evolve. Researchers at the Oak Ridge National Laboratory (ORNL) in Tennessee don't know what the next device will look like, but they believe they know what it will be made of: thin films of complex organic compounds. They report in the 21 February *PRL*, that they have produced reversible changes in electrical resistance in molecule-sized regions of organic thin films. The results help pave the way for making thin-film storage devices because they mark the first time anyone has demonstrated reversibility—needed for “writing” and then “erasing” data—at a molecular level.

Other researchers have shown they could induce changes in conductance—the equivalent of “writing”—to a thin film, says Karl Solberg, a theoretician with the Oak Ridge group, but using only heat or laser pulses, they haven't been able to “erase,” or reverse, the transitions without clearing entire regions of the film, as if shaking clear a whole Etch-a-Sketch.

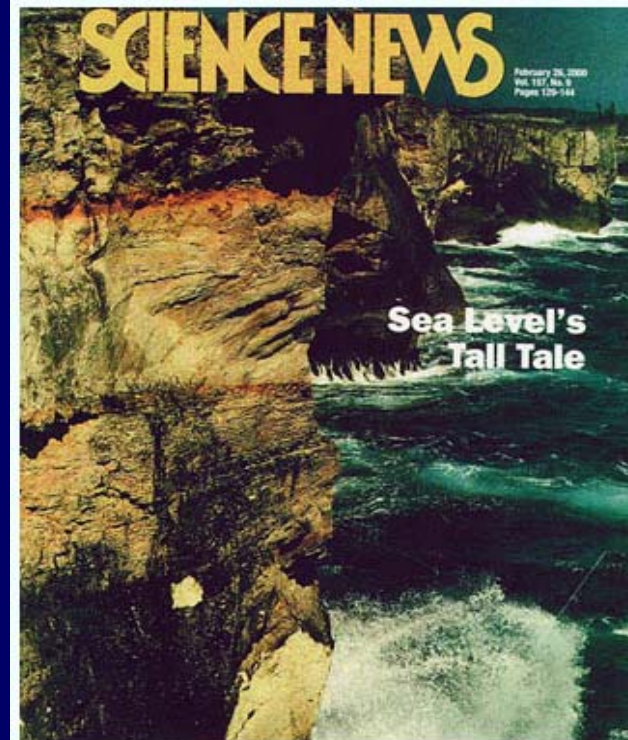
Solberg says organic compounds have piqued the interest of data-storage makers because of their incredible storage capacity. A typical CD-ROM, for example, has a storage density of about  $10^8$  bits per  $\text{cm}^2$ . The thin films used by the ORNL group and their colleagues at the Chinese Academy of Sciences in Beijing and the University of Chicago can store  $10^{14}$  bits per  $\text{cm}^2$ —a million-fold increase. Solberg says that organic-based data storage will ultimately create headaches for the engineers who have to design the machines fast enough to read from and write to such materials, but “that's the engineering hurdle.”

The team made films of a complex of two organic molecules on a graphite surface. By applying a range of voltages



© 2000 Photonix, Inc.

Today's technology. Like punch cards and floppy disks, CD-ROMs may become obsolete if organic thin films live up to their potential for storing a million times more data.



### Manhandled molecules, midget memories

Gangsters break someone's arm to deliver a message, leaving a powerful impression that may never go away. Now, a team of Chinese and U.S. scientists finds that roughing up organic molecules also can leave an enduring, though small, memory. In this case, however, some reverse strong-arming can quickly wipe out that memory.

Today's CD-ROMs squeeze 160 million bits into each square centimeter of recording surface. In the Feb. 21 *Physical Review Letters*, Hongbin Gao of the Chinese Academy of Sciences in Beijing and his colleagues report writing and erasing data in minute dots. These dots could potentially be crammed together to store information a million times more densely than CD-ROMs do and top even hard disks by a factor of nearly 100,000. However, the lab accomplishment remains far from commercial realization, the experimenters caution.

“This is very attractive work. It probably has applications as an organic [chemical]-based memory,” comments James M. Tour of Rice University in Houston, Tex. Gao, currently a guest scientist at Oak Ridge (Tenn.) National Laboratory, and

the researchers have considered a class of carbon-based materials, called conjugated organic compounds, that show unusual electronic properties.

For many of the compounds, the molecules have positively and negatively charged ends. This polarization makes them pickovers for electric fields, which exert forces on the charged regions.

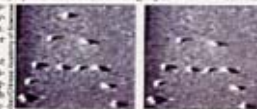
Turning two such compounds, 2,6-bis(methylammonio) and 1,4-bis(methylammonio) into a thin, electrically resistive coating on graphite or glass plates. By applying positive voltage pulses with the probe of a scanning tunneling microscope, the Chinese team created tiny spots in the film with only a few thousandth the electrical resistivity of the rest of the film. Each spot was a nanometer or less in diameter.

“The researchers found that the spots hold their low resistivity until subjected to negative voltage pulses, which restore them to the high-resistivity state.”

with scientists at the Oak Ridge lab and the University of Chicago. In a series of experiments, the collaborators discovered that the applied positive voltage transforms a patch of organic material into a disordered, or amorphous, arrangement, which is much less resistive than the ordered crystalline film.

The voltage pulse wrestles the polarized molecules into their new configurations. They get torqued, twisted, and all disoriented,” says Karl W. Solberg of Oak Ridge. A pulse of opposite polarity reshapes the molecules with the lattice.

The number of molecules affected must be very small, the researchers argue, since each spot roughly covers one unit of the crystal structure. “If you're talking about reconfiguring individual molecules, we are certainly very close to that limit,” Solberg says.

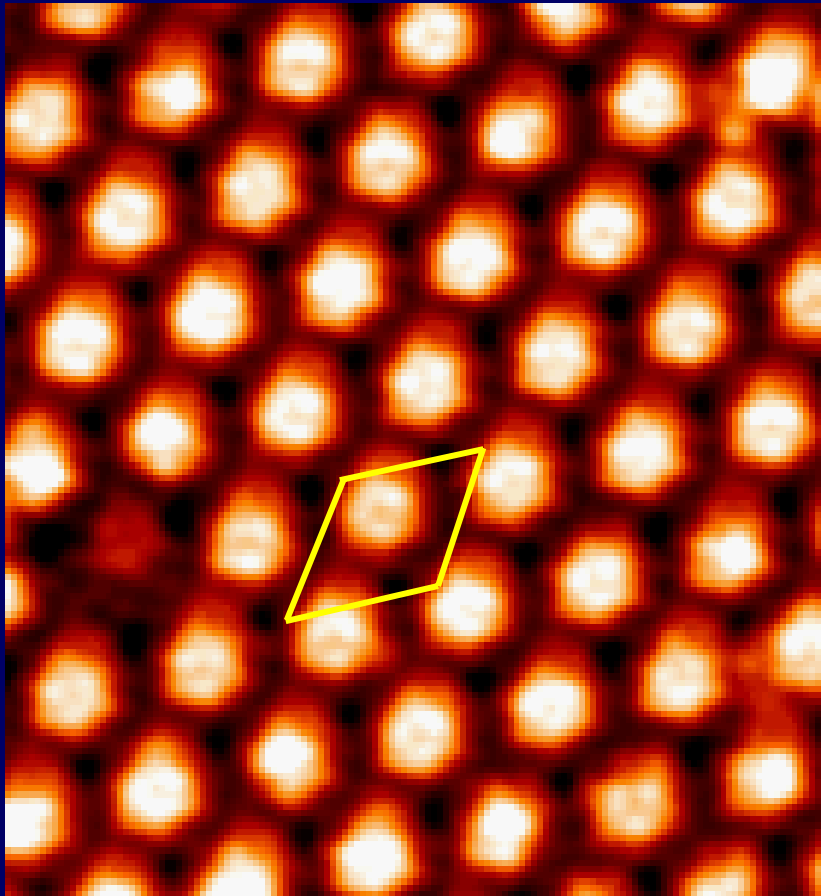


Nanometer-size bright spots, indicating low resistivity.

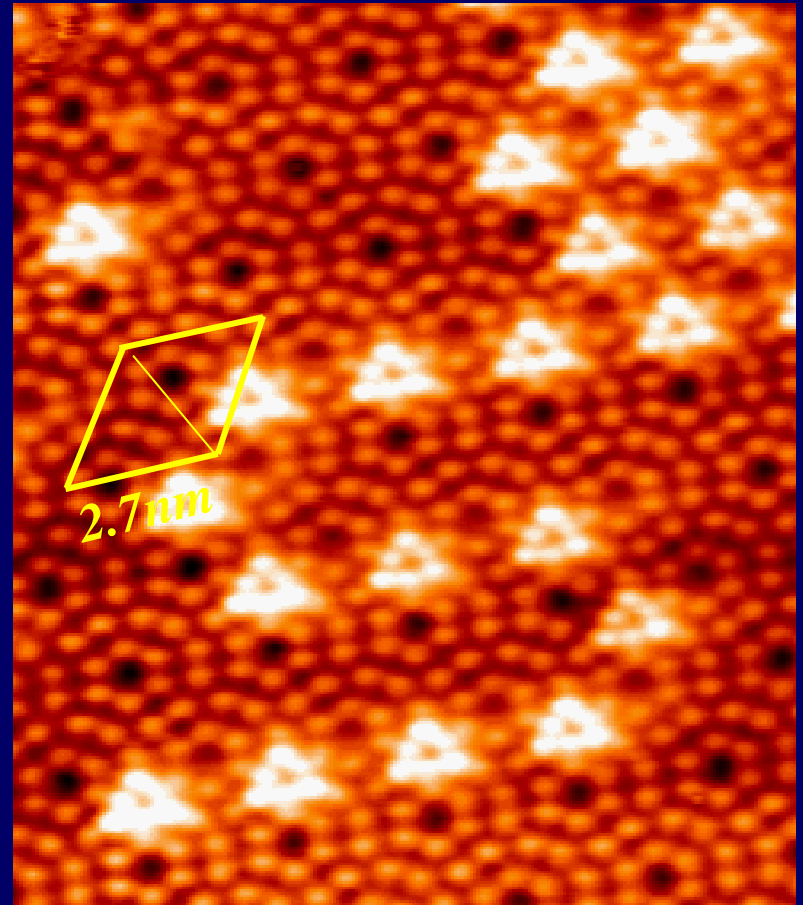


# Growth of Identical In Nanodot Array on Si (111) Surface

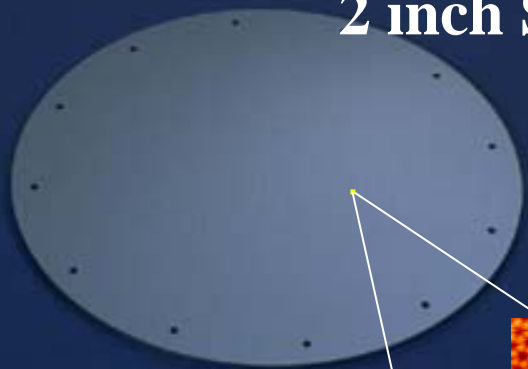
Empty States at +1.5V



Empty States at +0.6V

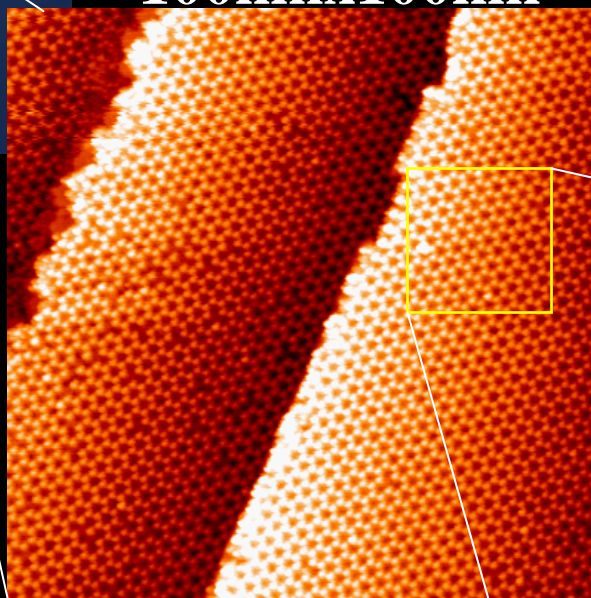


2 inch Si wafer

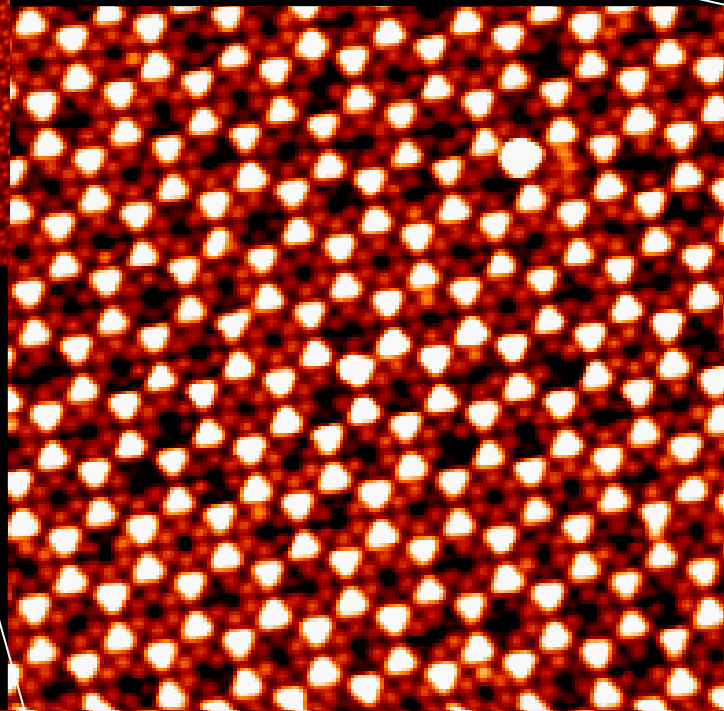


New Matter :  
二维人造晶格

100nmx100nm

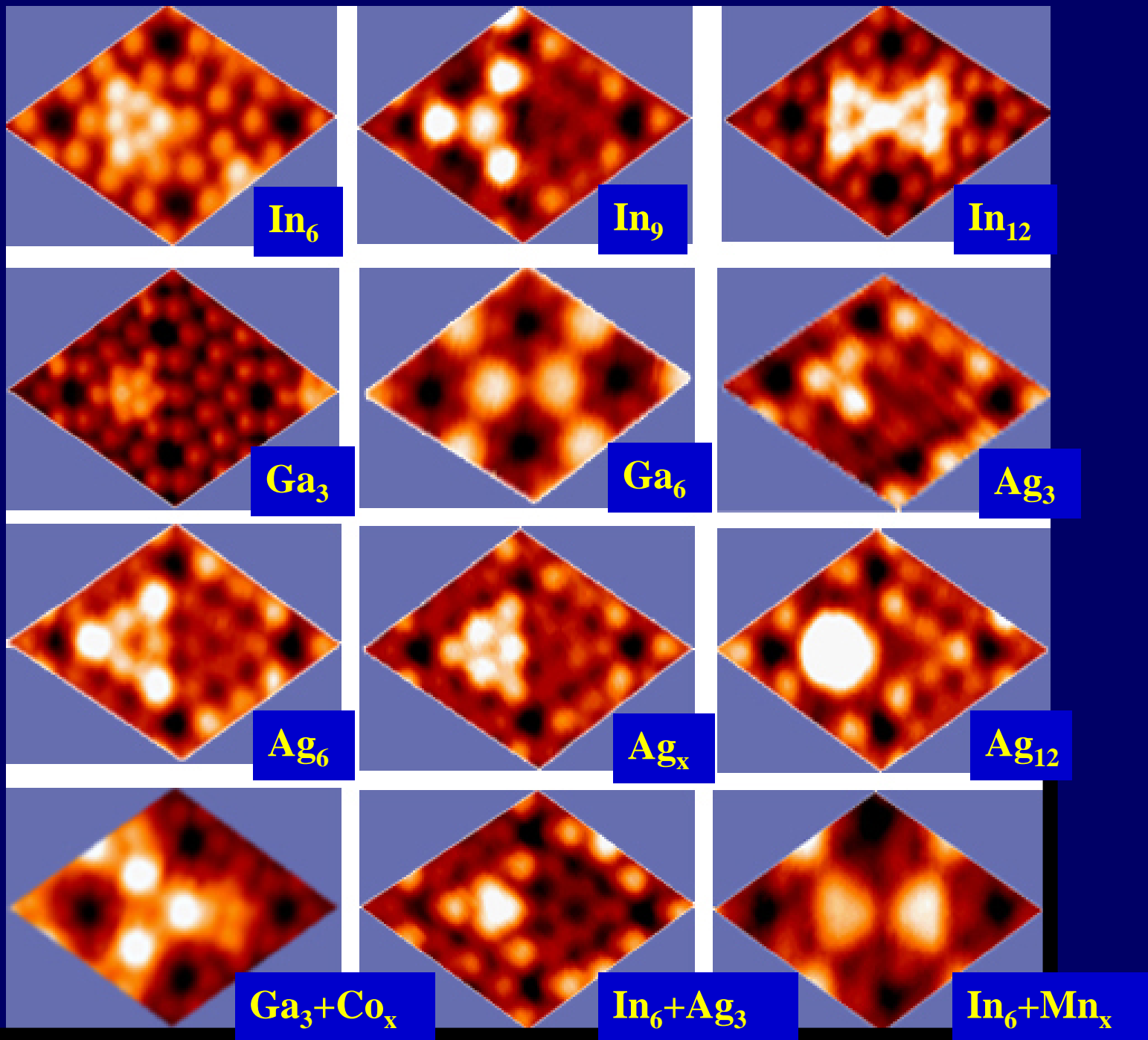


27nmx27nm



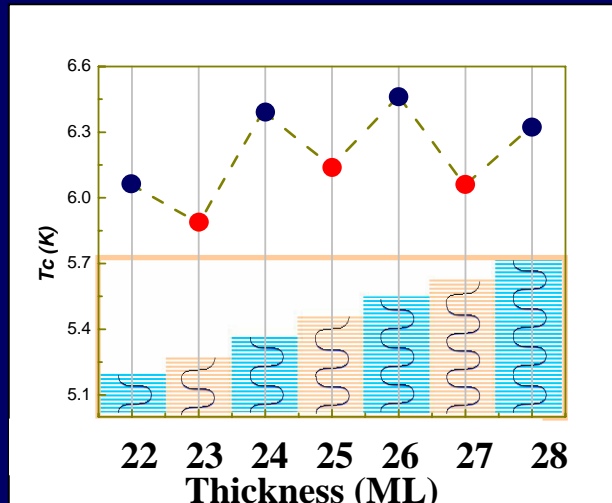
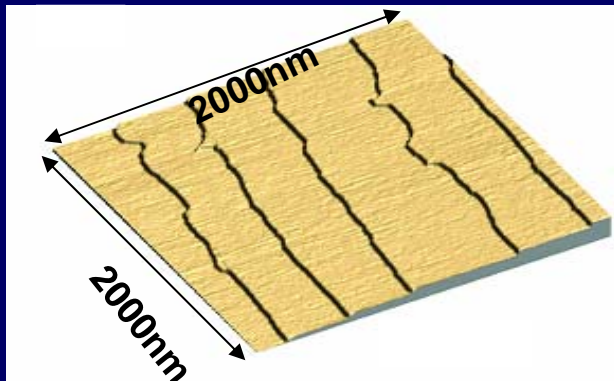


# 16种不同的点阵



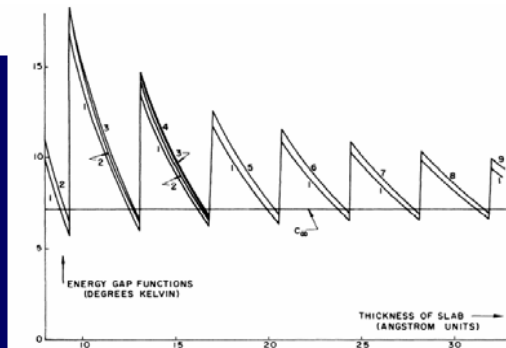
# Oscillation of superconductivity vs film thickness

BCS theory states that  $T_c$  depends on the electron density at Fermi level. We indeed found the  $T_c$  oscillation between 6K and 6.5K with the expected period of 2 atomic layers.



Guo et al.,  
*SCIENCE* 306,  
1915 (2004)

VOLU PHYSICAL REVIEW LETTERS 15 April 1963



superconducting energy gap parameters  $C_n$ , vs thickness of film. At each resonance, a new value of  $C_n$  is observed. All values of  $C_n$  are shown for small thicknesses; thereafter, only the largest and smallest to avoid confusion. The peak heights lie well above the bulk value,  $C_\infty$ , which is also shown on the graph. The width of the resonances is too small to show on the scale of the distance between resonances equals one half of the deBroglie wavelength of an electron at the temperature of the experiment. The parameters used for this figure were  $N/V = 2 \times 10^{22}$  electrons/cm<sup>3</sup>,  $\rho = 0.3$ , and  $\hbar\omega_c = 100^\circ\text{K}$ .

J. M. Blatt and C. J.  
Thompson,  
*Phys. Rev. Lett.* 10, 332  
(1963)

## Science PERSPECTIVES

### Superconductivity in Thin Films

Tai-Chang Chiang

An oscillatory dependence of  $T_c$  on film thickness is a far more convincing proof for quantum size effects. Some prior studies suggested such oscillatory behavior (7, 8), but the report by Guo et al. (2) is the first definitive and quantitative

Since the 1960s (1), researchers have explored the possibility that the superconducting properties of thin films may be superior to, or at least different from, those of bulk materials. Guo et al. now demonstrate on page 1915 of this issue (2) that film thickness can indeed affect superconducting behavior. Their data show convincingly that the superconducting transition temperature ( $T_c$ ) of thin lead films oscillates with film thickness.

As the thickness of a film is reduced to the nanometer scale, the film's surface and interface confine the motions of the electrons, leading to the formation of discrete electronic states known as quantum well states (3). This quantum size effect changes the overall electronic structure of the film. At small thicknesses, physical properties are thus expected to vary, often dramatically, with thickness.

Recent experimental studies have demonstrated such variations with film thickness for properties such as the electronic density of states, electron-phonon coupling, surface energy, and thermal stability (4-8). The variations are expected to follow a damped oscillatory curve that is superimposed on a  $\pm N^2$  baseline (where  $N$  is the number of atomic layers in the film and the exponent  $\gamma$  is often close to 1).

The superconducting transition temperature for a metal such as lead depends on

The author is in the Department of Physics and the Frederick Seitz Materials Research Laboratory, University of Illinois, Urbana, IL 61801, USA. E-mail: [chiang@mit.uiuc.edu](mailto:chiang@mit.uiuc.edu)

### THIS WEEK IN Science

edited by Stella Hurley and Phil Szurovi

#### Semiconductors in a Spin

A current flow through a conductor in a magnetic field leads to a measurable voltage in the transverse direction (the Hall effect). Recent theoretical work has predicted the existence of an analogous effect for the spin in semiconductors, the spin Hall effect. Kato et al. (p. 1910, published online 11 November 2004; see the 12 November news story by Service, the cover, and the Perspective by Bauer) present experimental data confirming the accumulation of net spin on opposite sides of a GaAs sample. The ability to create and detect a spin current in a nonmagnetic material, without the need for an external magnetic field, may lead to applications in spin electronics.

#### Large Shallow Quakes

An estuary along the eastern coast of Japan shows evidence for multiple episodes of uplift during the past few hundred thousand years, but the cause of this uplift is poorly understood. Sawai et al. (p. 1918) found a tsunami deposit closely followed by a series of uplifted mudflats that formed in the 17th century. The large size of the tsunami along with the large amount of uplift indicate that a large megathrust occurred along the subducting plate, probably produced by transient creep or mantle relaxation for tens of years.

#### Oscillatory Superconductivity

When the thickness of films approach several monolayers, quantum size effects may result from the confinement of electrons in the vertical direction. The work has predicted that quantum size effects should also appear in thin superconductors as a well-defined oscillation of the transition temperature  $T_c$ . Guo et al. (p. 1915) in the Perspective by Chiang) produced thin Pb films whose thicknesses were controlled to within a single monolayer. The superconducting transition temperature for a metal such as lead depends on

#### Recombination and Diversity

DNA recombination may represent eukaryotes and a major source of ad

in bacteria. The role of recombination in the third branch of life, Archaea, has not been clear. Papke et al. (p. 1928) analyze a population of haloarchaea in solar salters near Alicante, Spain. The association of gene alleles is essentially arbitrary.

**Nanotech 2005**  
 Health Care Materials Transportation Energy  
 Nanobiotech Surfaces Personal Care Food  
 Environment Telecom Displays Optics Polymers  
 Electronics Simulation Design Coatings

2800 Attendees 150+ Exhibitors  
 500+ Talks 100+ Startups  
 200+ Nanotechnology Ventures  
 Nanotechnology Impact Workshop

**TANABE MEDICAL FILMS**  
 田辺製薬株式会社  
 田辺製薬ホームページ >>>  
 医療関係者の皆様へ  
<http://physicsweb.org/>  
 2004/12/09

#### Advanced Member

Posts: 321

Member No.: 38

Joined: 16-April 04

## Nature 3次; Science 3次;

...

چين و ايلات - متحد  
 ك مستقيماً به كلفتي ي  
 ن - علوم - چين دريكن،  
 نازك - سرب به تعداد -  
 ا ي نازك مي سازند.  
 مقيد به لايه‌ها ي نازك -  
 ها ي چاه‌كوتامي كوالتيده  
 نزدیکی ي تراز - فرمی [3]  
 ي لايه اثر بگذارند.  
 ، [4] ، و دانش‌گاه - كليقينيا  
 ها ي بلورين - سرب رشد  
 ها ي با كم‌تر از 22 زيرلايه،  
 پس خفته وهم‌كاران - ش  
 درما ي است به زير - آن

ایش - تعداد - تک‌لايه‌ها  
 دما ي كدر زياد مي‌شود. از ان پس با افزايش - تعداد - لايه‌ها دما ي گذار نوسان مي‌كند  
 و لايه‌ها يي كه تعداد - تک‌لايه‌ها پيشان زوج است، نسبت به آن‌ها يي كه تعداد -  
 تک‌لايه‌ها پيشان فرد است  $T_c$  ي بيش‌تر ي دارند.

### Forum.Hemij

Главна страница | Линкы

Кон врвот | П

Нова тема

Ваше име:

Ваша email ад

Тема:

Новости на Не

Суперпровод

со нивната деџ

Куп Хие и сорџ

откриле дека џ

бројот на атом

КОМЕНТАР:

### Supercon to nano-s

The critical temperatu controlled by changing

From **Margriet J Van Baal** and **Reinh** in the Laboratory for Solid State Pt and Magnetism, Katholieke Univie Leuven, Belgium

Imagine measuring the electrica of a perfect rectangular copper reduced in thickness, layer by la What would happen? Initially th would increase smoothly as the c of the bar became smaller, all electrons in the bar would rem move in any direction. But as when the thickness reached the range, the motion of the elect vertical direction would be resti This confinement can give r ordinary physical properties. N **Norie** of the Chinese Academy of **Hemij** and co-workers have bu superconducting transition tem the temperature below which th drops to zero - of thin film m varies with the number of atom the film (Y Guo et al. 2004 *Science*

**Super states**  
The motion of electrons in a thin ponds to the textbook example e particles in a box, and is best un treating the electrons as wave p particles. When confined with ultrathin layer, the electrons can certain "quantum well" states th correspond to standing waves acro the thickness of the film, similar to the standing waves along the length of an organ pipe. In fact, only a small fraction of the huge number of electrons in a material is involved in physical processes such as conductivity

24

**visit today** **More Flexibility**  
**nature physics portfolio**  
 research highlights  
 In brief: just like that  
 Physical Review Letters **88**, 060201  
 (25 January 2005)  
 The spontaneous formation of periodically ordered nanocubular arrays of metal atoms on a Si(111)-(7x7) surface has been demonstrated - a process that could find practical applications in microelectronics and nanotechnology. The identity of the clusters arises not only from the features of the Si substrate, but also from the "magic" number of atoms they contain.

**Spin SEARCHES**  
 SEMICONDUCTOR SYSTEMS | ADVANCED | JOB P | INSIDE | E.O.D | COMM | PLANET | EMBED | PRODU | AUTOMOTIV | POWER MANAGEMENT | DESIGN LINE | VIDEO/IMAGING DESIGN LINE | WIRELESS NET DESIGN LINE

**Carbon Nanotubes Yield A New Class Of Biological Sensors**  
 Nanotechnology researchers at the University of Illinois at Urbana-Champaign have demonstrated a tiny, implantable detector that could one day allow doctors to monitor blood glucose levels continuously - without ever having to draw a blood sample.

**Purdue Engineers Create Model For Testing Transistor Reliability**  
 Researchers at Purdue University have created a "scaled model" for predicting the reliability of new designs for silicon transistors - a potential tool that industry could use to save tens of millions of dollars annually in testing costs.

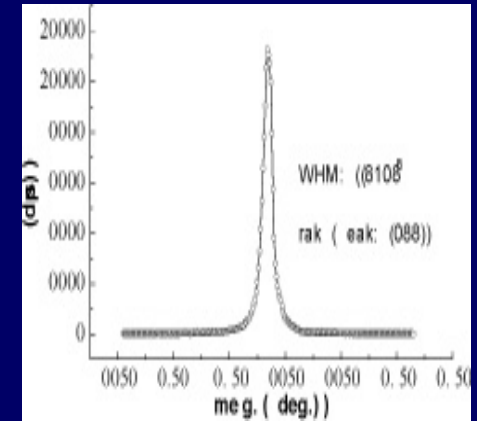
**Lower-cost approach**  
 By using hydrogen-bonding reactions, the group demonstrated that ele films can be fabricated on silicon, glass, ceramic and organic-polymer s method is said to offer a lower-cost approach that nevertheless impro

**University of Illinois at Urbana-Champaign**  
 Institute of Physics CAS  
 I n s t i t u t e o f P h y s i c s C A S  
 P h y s i c s C S



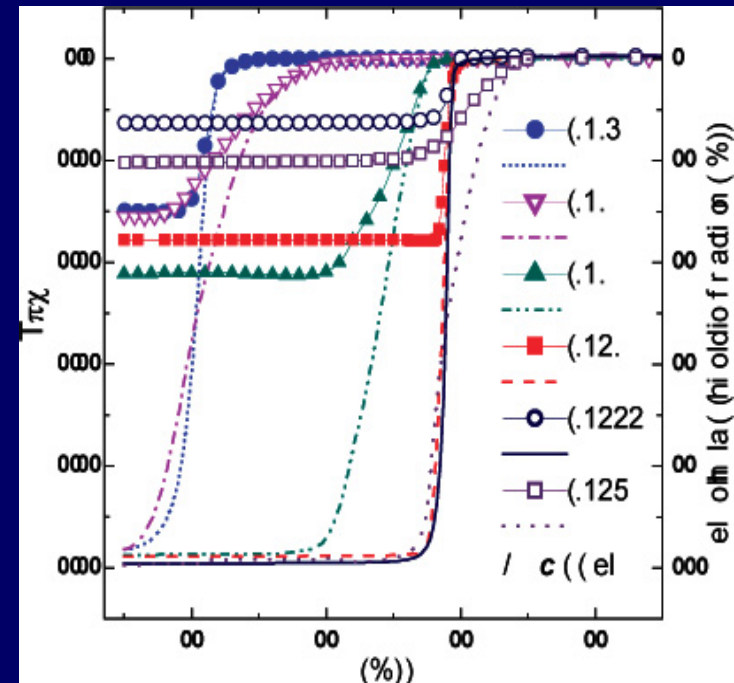
# La<sub>2-x</sub>Sr<sub>x</sub>CuO<sub>4</sub> crystal

Universal nodal Fermi velocity; X.J. Zhou,  
F. Zhou, J.W. Xiong, Z.X. Zhao et al.,  
*Nature*, 423 (2003)398



High quality large scale LaSrCuO  
crystals are grown by TSFZ  
method;

T<sub>c</sub> changes at hole concentration:  
x = 1/16 and x = 1/9, magic  
numbers;

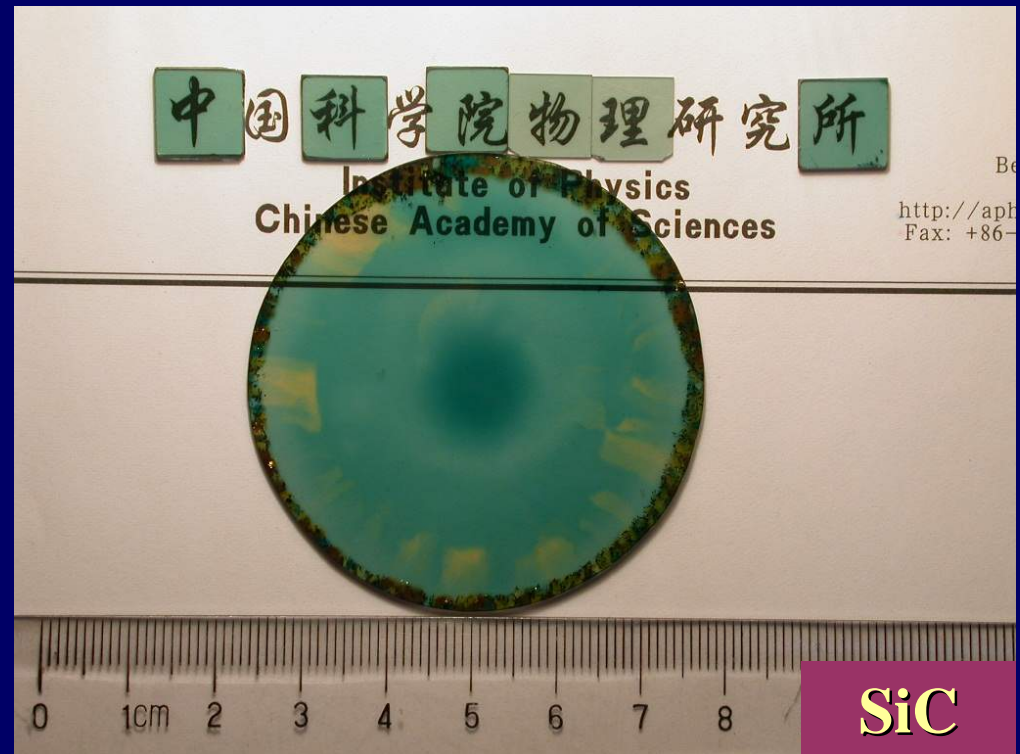


# SiC Crystals

**High quality SiC crystal with 2 inch in diameter;**

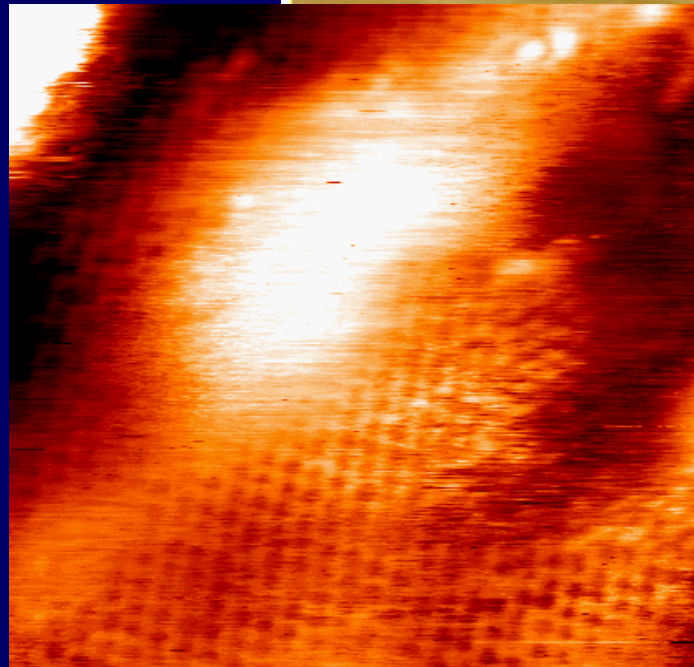
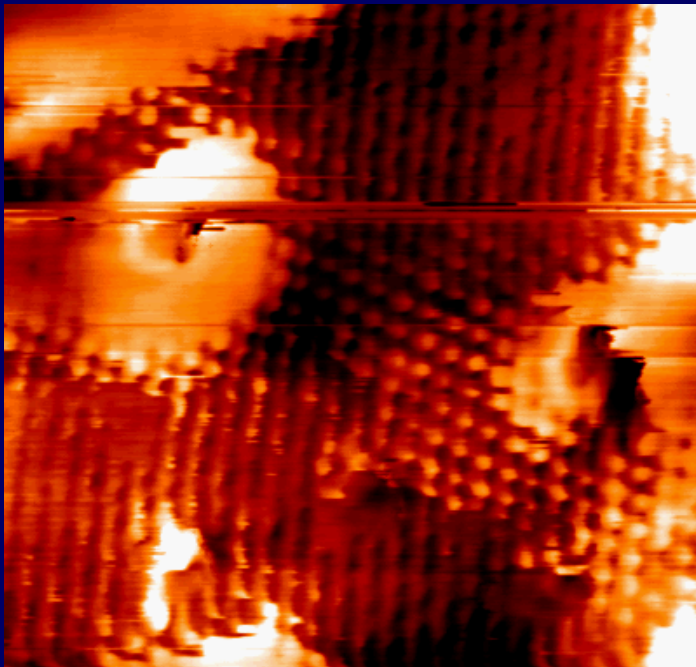
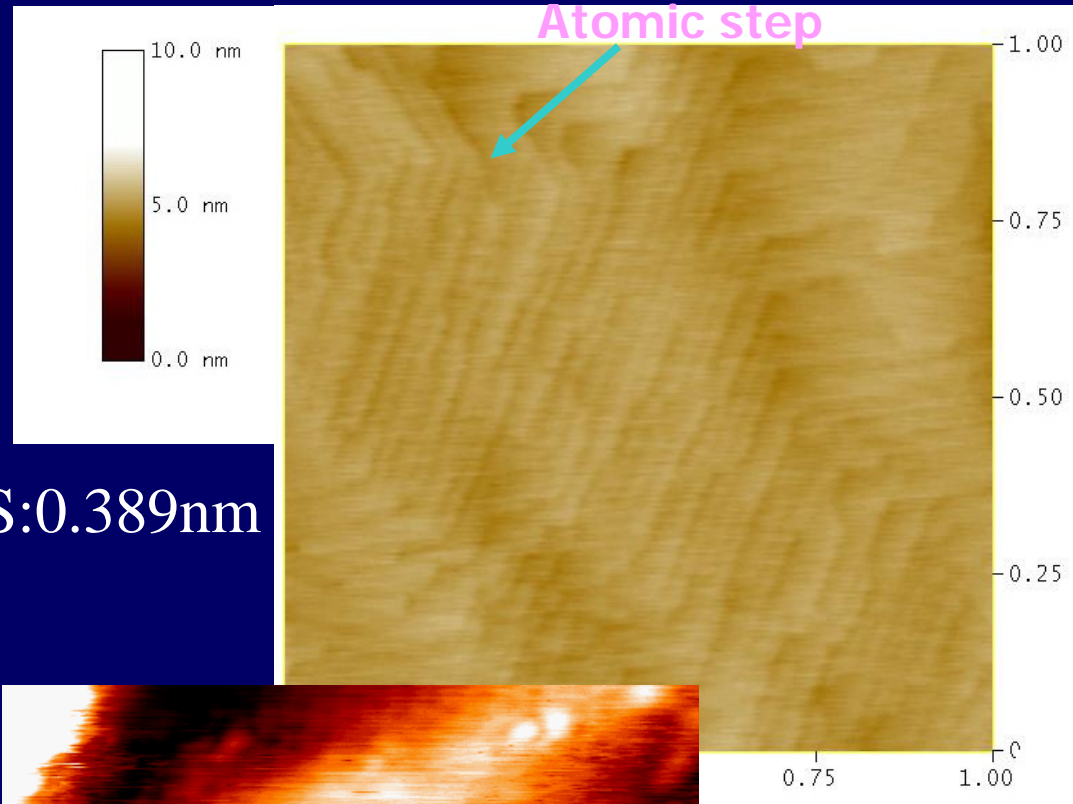
**Defects < 100/cm<sup>2</sup> for 10x10 mm<sup>2</sup>;**

**(Better than that of Cree)**



# ZnO surface with atomic flat

RMS:0.389nm

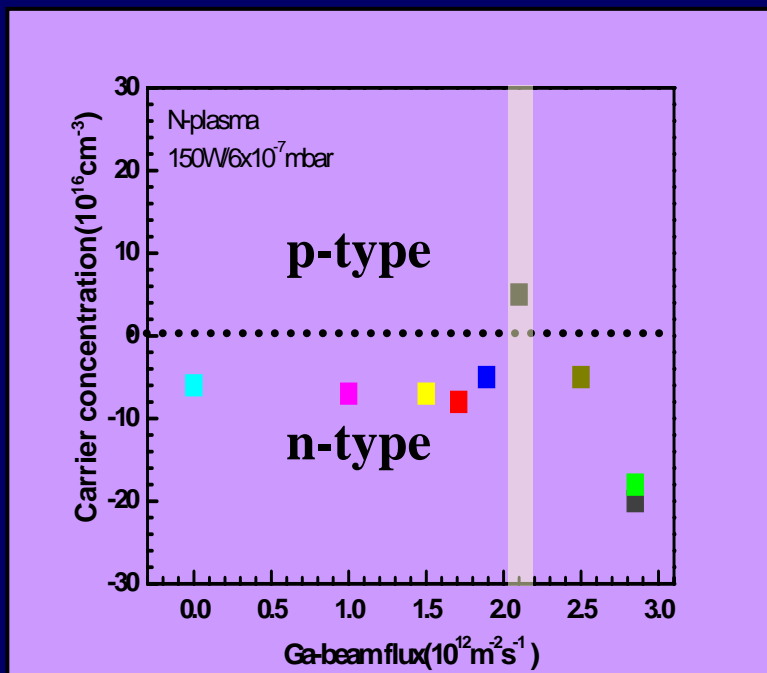




# p-type ZnO crystal film

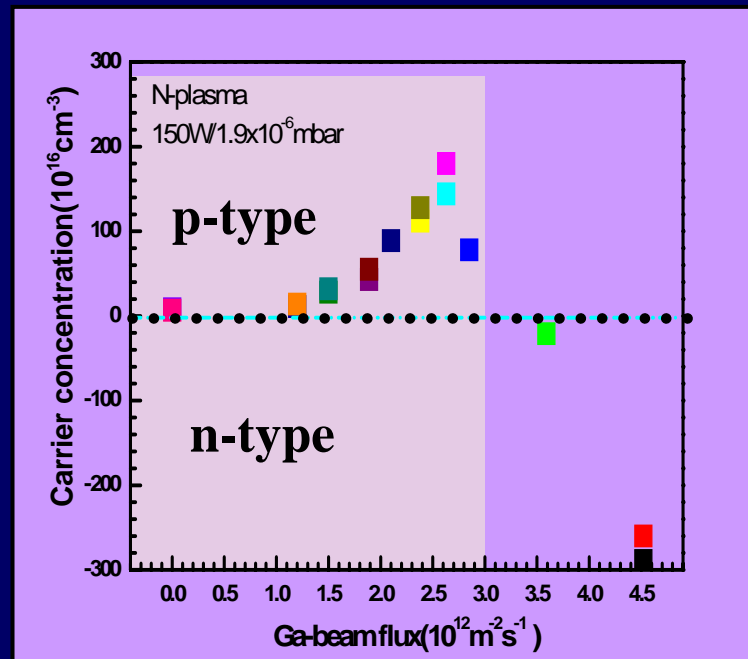
## ❖ Ga+N co-doping

- Narrow codoping window
- Low hole concentration:  $5 \times 10^{16} \text{cm}^{-3}$

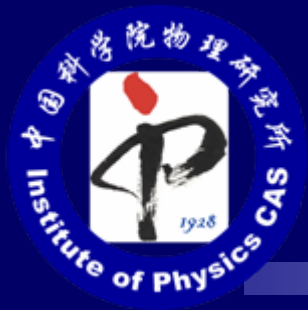


## ❖ Li+Ga+N triple-doping

- Much broader window
- High hole concentration :  $3.6 \times 10^{18} \text{cm}^{-3}$

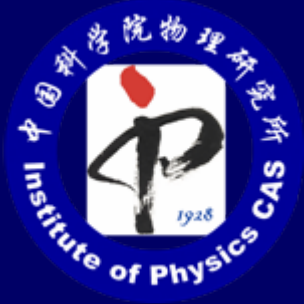


ZnO基p-n同质结发光二极管的研制获得较大进展！



# Evaluation

---



## **Institute review process**

- **Performance measures include science and technology excellence, mission impact, facility operations; (impact on science; success in long-term, ...)**
- **Annual performance reviews for all research groups (impacts salary and promotions);**
- **All projects and facilities undergo competitive peer review (every 3 years): 2-step review process;**
- **The institute is reviewed annually by CAS: Science and technology, operations, community service and outreach.**



# 2005. 1

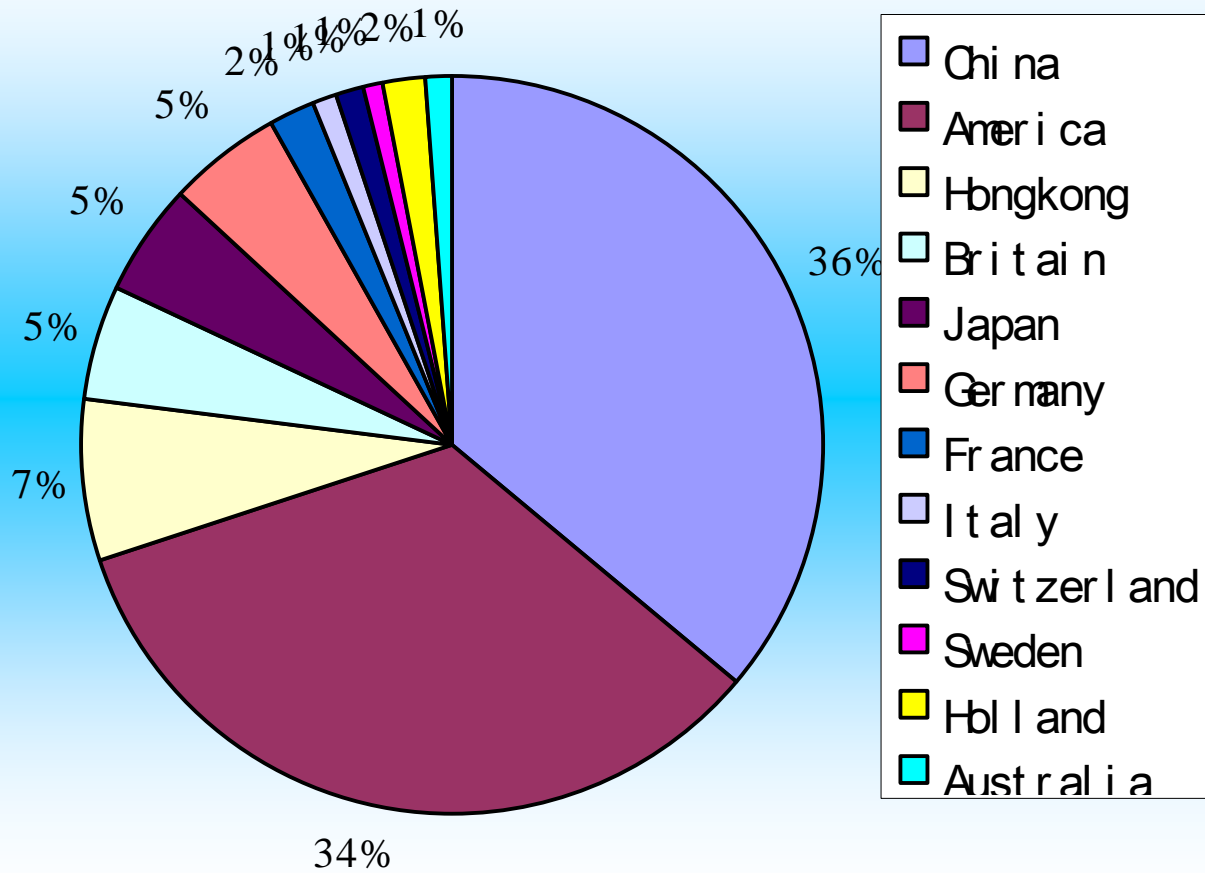
Research groups: 45 in the period of 2005.1 -  
2007.12;

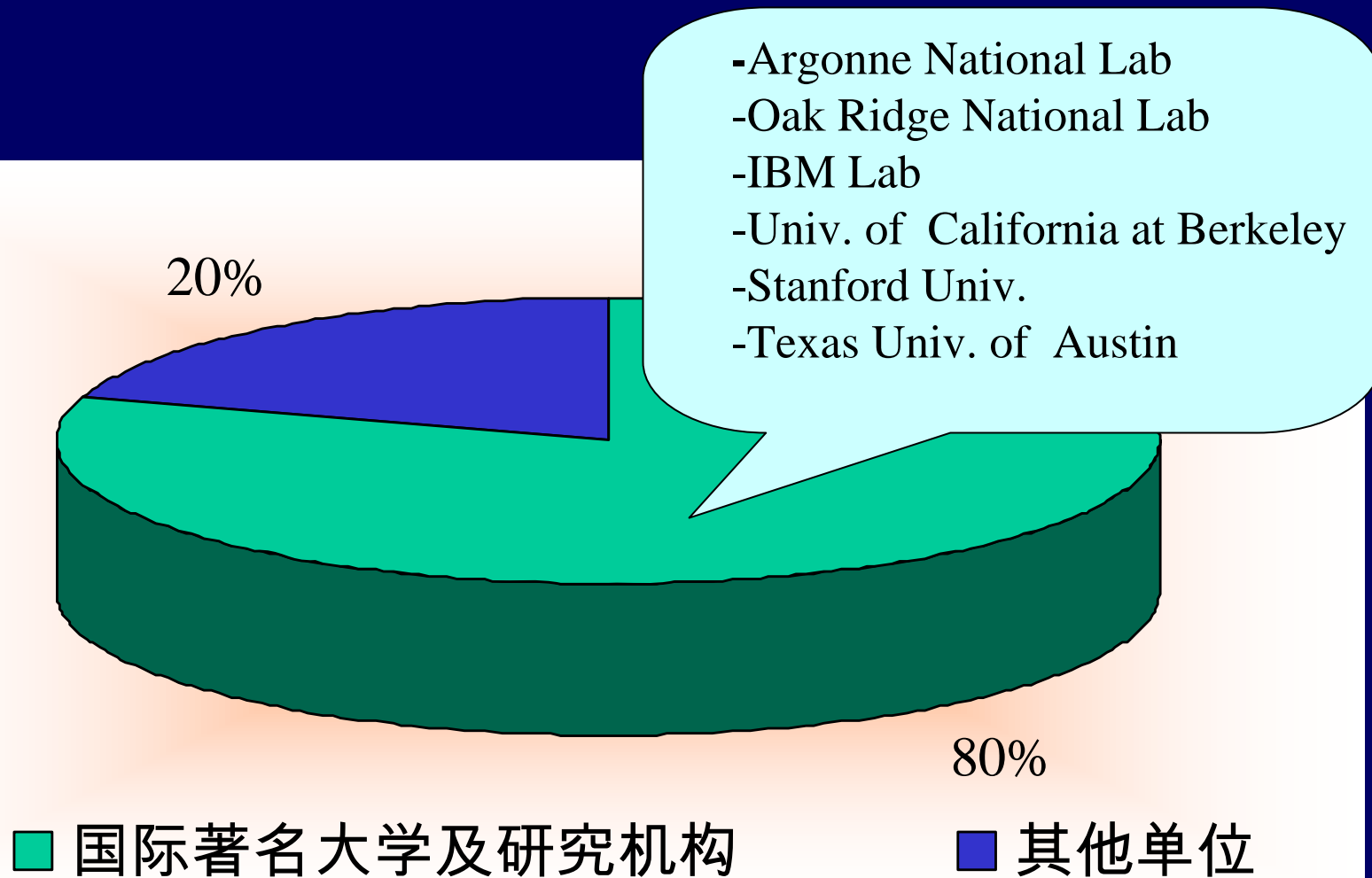
(new groups: 7, new group leaders (PI): 14)

Total changes  $> 1/3$  for every 3 years.

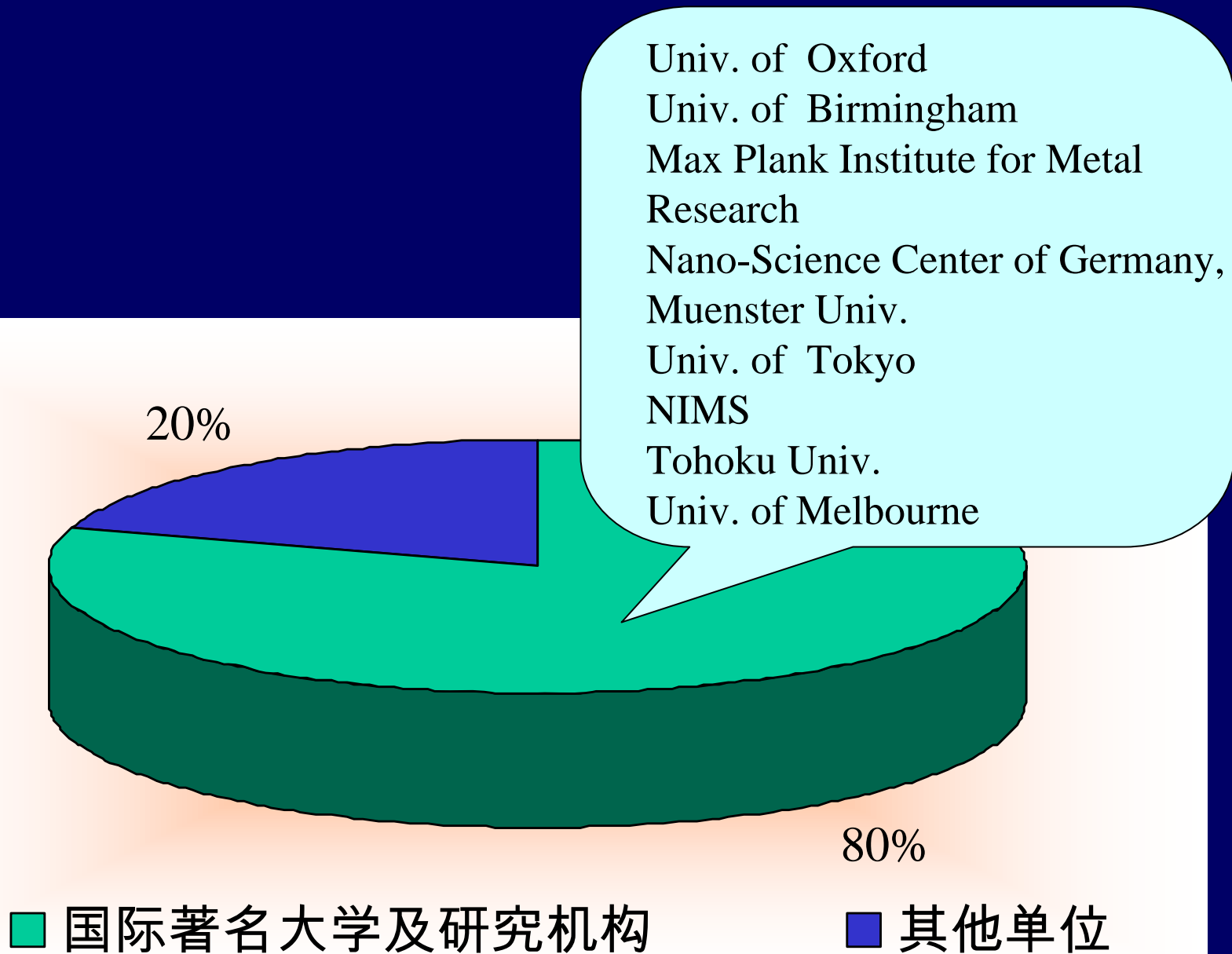


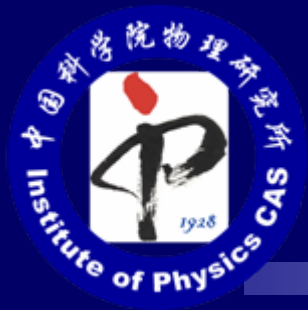
## Reviews by Country





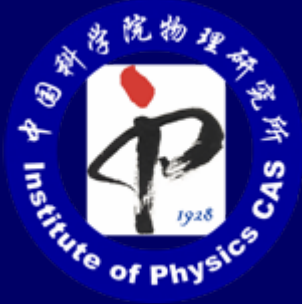






# Attracting New Staff

---



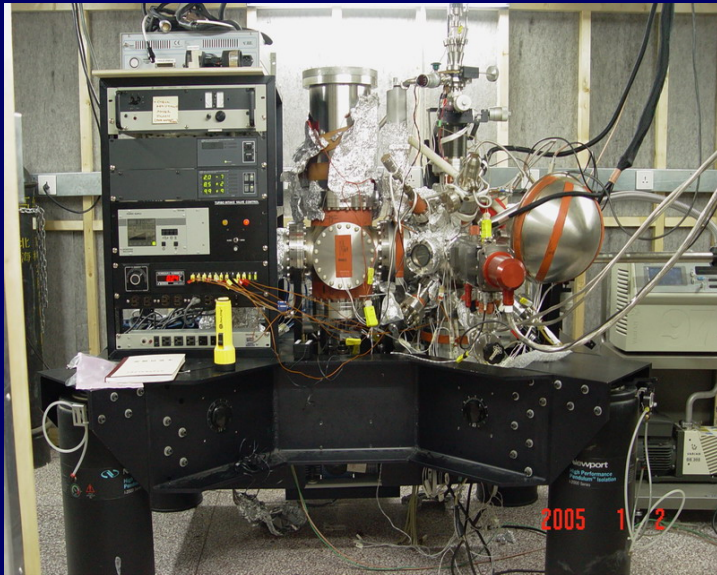
## **Policies to encourage and attract new staff**

- **CAS 100 talent program (highly competitive 3-year grants for new staffs at Asso. Prof. level);**
- **IOP talent program (highly competitive 2-year grants for new staffs at Assi. Prof. level);**
- **Distinguished scientist program (Full Prof. position);**
- **Strategic hire program (support for promising new staff in critical areas at all levels);**
- **“Star of the Year” Award for young and new staffs.**

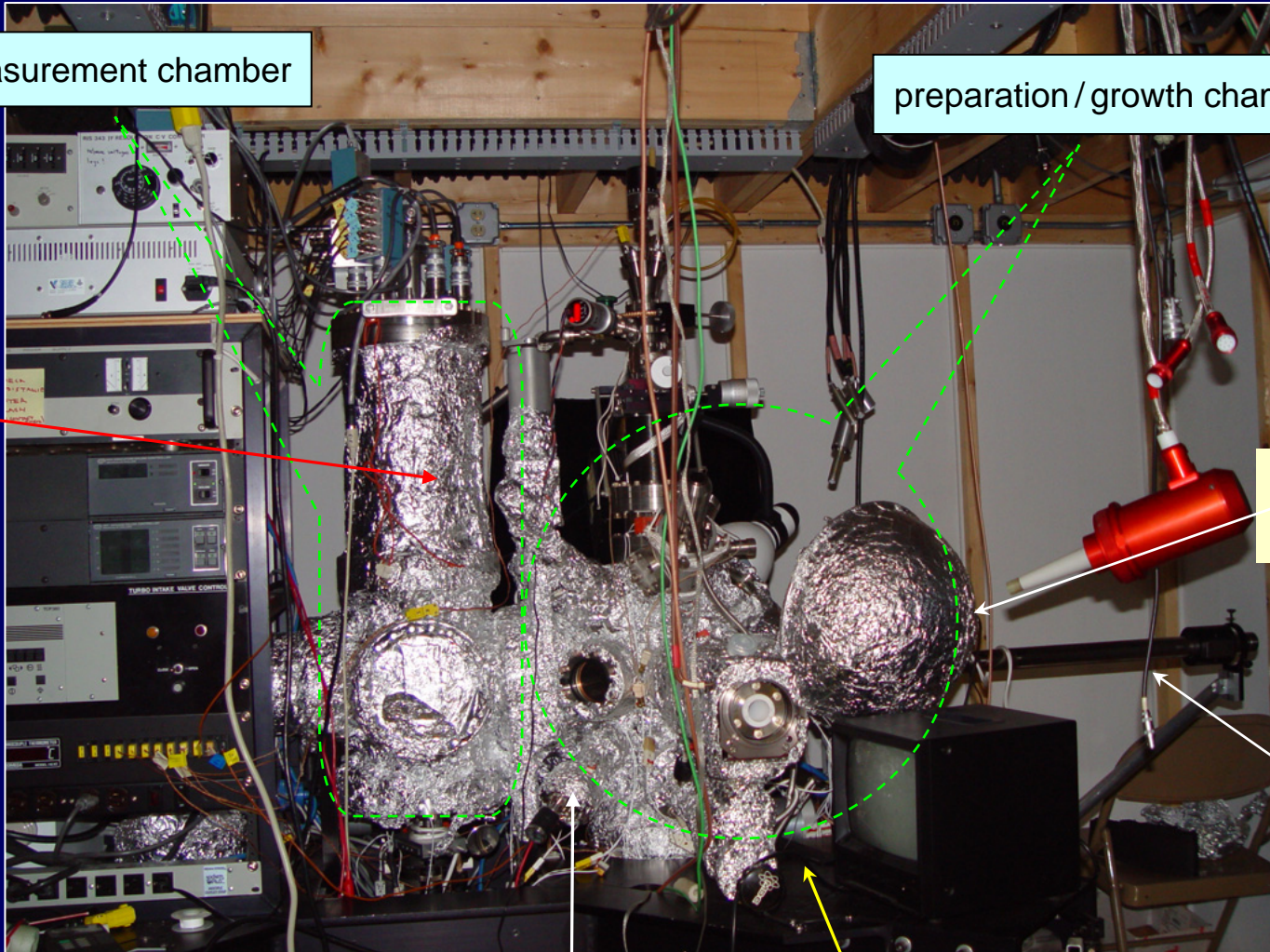


# Lab for Solid State Quantum Information and Quantum Computation

---



**Prof. D.M. Chen (2004.2 - )  
Harvard Univ. (1990.12-2004.1)**



measurement chamber

preparation / growth chamber

STM cryostat (5 - 300 K)

Auger spectrometer

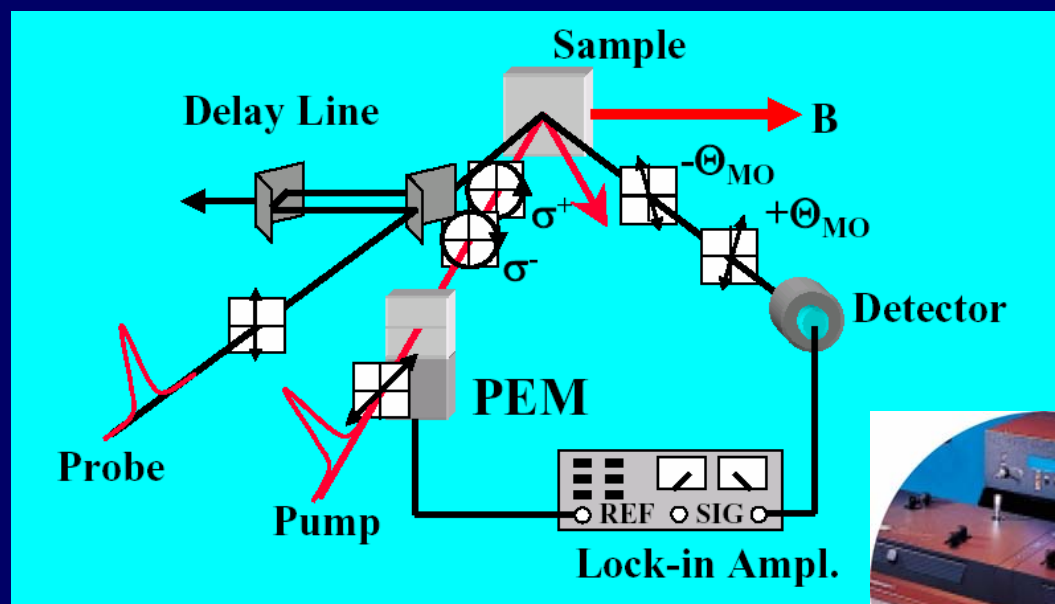
Sample load lock

Evaporator Total of 6

RHEED



# Spin Dynamics Measurement System (超快自旋动力学测量系统)



锁模掺钛蓝宝石脉冲激光器

双腔结构：120fs & 2ps ( 10ps )

波长范围：700-980nm；扩展波长：350-480nm

磁光超导磁系统

温度范围：4.2K ~ 300K；水平磁场：8T

# Outstanding young researchers: 44

---

**Prof. DM Chen (Harvard U)**

**Prof. XC Xie (OK State U)**

**Prof. SW Gao (Chalmers U)**

**Prof. HX Xu (Lund U)**

**Prof. XJ Zhou (LBNL)**

**Prof. JR Shi (UT Austin)**

**Prof. JD Guo (ORNL)**

**Prof. H Fan (UCLA)**

....



**March 2005, LA**



# Star of the Year 2004

## Young Researcher Golden Symposium

祝贺方忠博士荣获物理所首届“科技新人奖”



方忠 博士

中国科学院“百人计划”入选者 (2003)  
国家杰出青年科学基金获得者 (2004)

### 学术经历

1987. 09 - 1996. 06 华中理工大学 学士、硕士、博士  
1996. 04 - 1996. 06 香港中文大学 访问学者  
1996. 10 - 2003. 04 日本产业技术总合研究所 (AIST) 研究员  
(其间2001. 01 - 2001. 08 美国橡树岭国家实验室 访问学者)  
2003. 04 - 中国科学院物理研究所 研究员、博士生导师  
量子模拟科学中心 主任

### 科研方向

1. 新型功能材料的电、磁、光学特性的第一原理计算研究;
2. 强关联体系中的奇异物性研究;
3. 有机材料、纳米体系、超晶格、表面及界面等的大规模量子模拟。

### 主要成果

多项研究成果发表于国际一流刊物 (包括Phys. Rev. Lett. 7篇, Science 2篇), 并被他人引用400余次。并应邀在国际大型学术会议作邀请报告, 如MRS年会、JPS年会、欧洲计算物理会议等。  
2000年发表在Science的文章, 被德国著名的OMICRON网站评为2001年1月的“The Result of the Month”。2003年发表在Science的文章, 通过对反常Hall效应的研究, 首次证明动量空间中磁单极的存在, 受到国内外同行的广泛关注。2000年获得日本原子技术联合研究中心 (JRCAT) 科研成果特等奖。

# Graduate Students

---

**Current Students: 586**

**M.S. degree: 214**

**Ph D degree: 372**

**Postdoc researchers: 22**

**(Most of the students from the top univs. in China)**

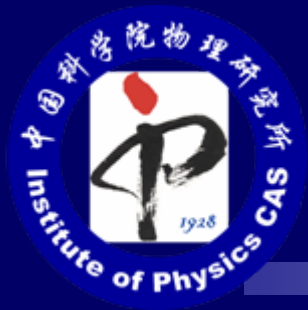
# Graduate Student Awards

---

Dr. J.R. Luo, ICDD Ludo Frevel (2005)

Dr. W.G. Zhu, MRS Graduate Student Silver Award (2004)

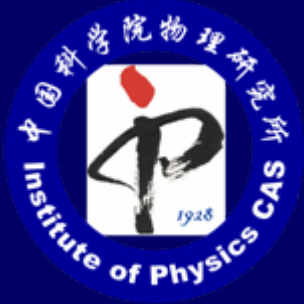
|                           | Place     | No. |                     | Place         | No.    |
|---------------------------|-----------|-----|---------------------|---------------|--------|
| CAS<br>President<br>Award | Excellent | 2   | 宝钢奖                 | CAS           | 2      |
|                           | First     | 5   | 宝洁奖                 | CAS           | 4      |
| 刘永龄奖                      | CAS       | 3   | Excellent<br>Thesis | CAS<br>Nation | 2<br>1 |



# International Collaboration

---

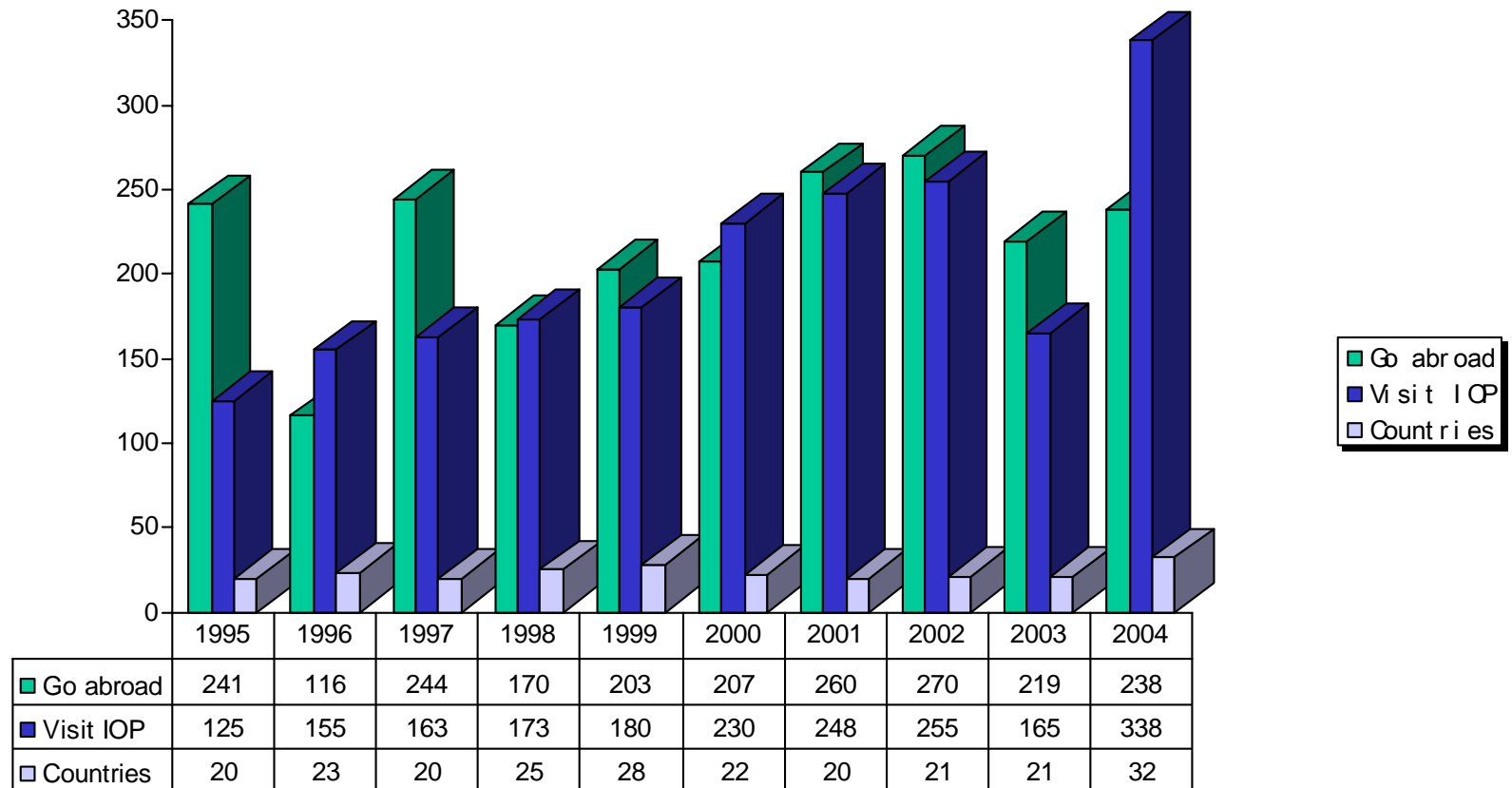




## **International collaboration**

- **User facilities**
  - **Open to all researchers based on independent review of proposals;**
  - **Instrumentation partnership;**
- **International agreements**
  - **Cooperative research;**
  - **Exchange agreements;**
- **Collaboration**
  - **Scientist to scientist;**
  - **Approximately 50 joint publications annually.**

# International cooperation & exchange





**Prof. Tord Claeson, Chairman of the Nomination and Selection Committee for the Nobel Prize in Physics of the Royal Swedish Academy of Sciences visiting the Institute.**



**Visit by R.Laughlin, Nobel Prize winner and Professor at Stanford University.**





**H. Rohrer, Nobel Prize winner and research scientist at IBM. Zurich laboratory in Switzerland, visiting the institute.**



**Daniel C. Tsui, Nobel Prize winner, being elected visiting professor in his visit , and a series lecture, *Daniel C. Tsui's Lecture* , was initiated after his name.**

# Daniel C. Tuis's Lecture (2004 - )

Lecture in honor of Professor Daniel C. Tuis  
崔琦讲座



中国科学院物理研究所  
Institute of Physics Chinese Academy of Sciences

**A new perspective on the superconducting transition in the cuprates: Enhanced diamagnetism and vortex-Nernst effect in the pseudogap state**

**Prof. Nai-Phuan Ong**  
Department of Physics  
Princeton University



N.P. Ong教授于1971和1976年先后在美国哥伦比亚大学和加州大学伯克利分校获硕士和博士学位。现任美国普林斯顿大学物理系教授。他的主要工作集中在强关联体系的电子输运性质研究,涉猎从超导体、铁磁体到增强热电势、自旋电流和铁磁体中的Berry相等凝聚态物理研究领域。一方面研究和阐明这些体系在电子-电子强相互作用下所表现出的奇异电阻、霍尔效应和热电势等特性;另一方面探索和研究这些体系处于铁磁、反铁磁和螺旋磁性等状态时其自旋有序是如何影响电荷的输运性质等等。过去20年里, Ong教授及其合作者在Nature、Science和PRL等杂志上发表学术论文近200篇,在国际学术界有重要影响。

报告时间和地点: 2004年10月19日(星期二)10:00-11:30AM  
中国科学院物理研究所 D212报告厅

- \* Prof. Nai-Phuan Ong  
Princeton Univ., 2004
- \* Prof. Sankar Das Sarma  
Univ. of Maryland, 2005



## \* The ZhongGuanCun Forum

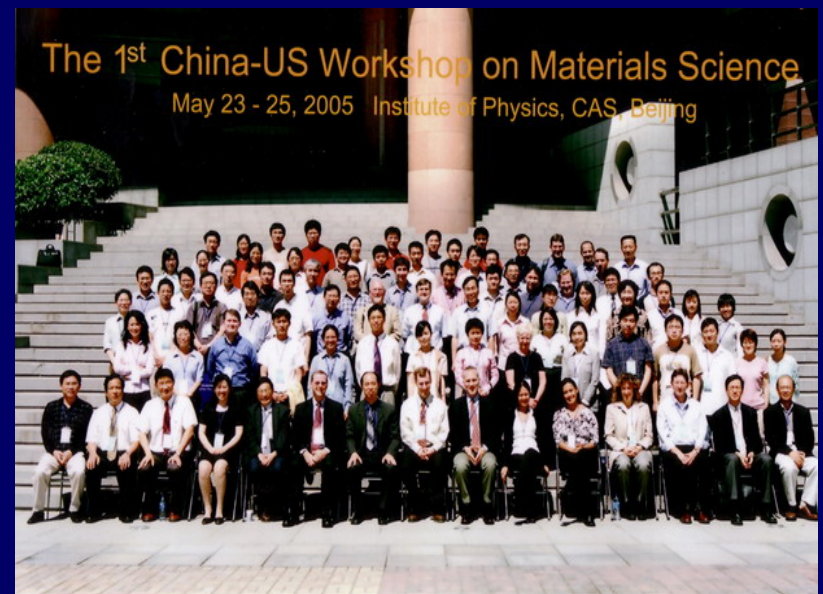
on Condensed Matter Physics: 65 (once/month)

(K.Takanashi,R. Snyder, H.J. Dai,T.C. Chiang, S.G. Louie, ... )

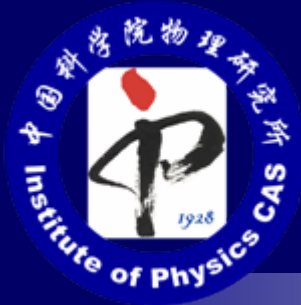
\* The Advanced Physics Forum: > 100 (twice/month)

\* Working Lunch: (twice/month)

\* ~ 10 intl confs./year and ~ 10 intl workshops/year

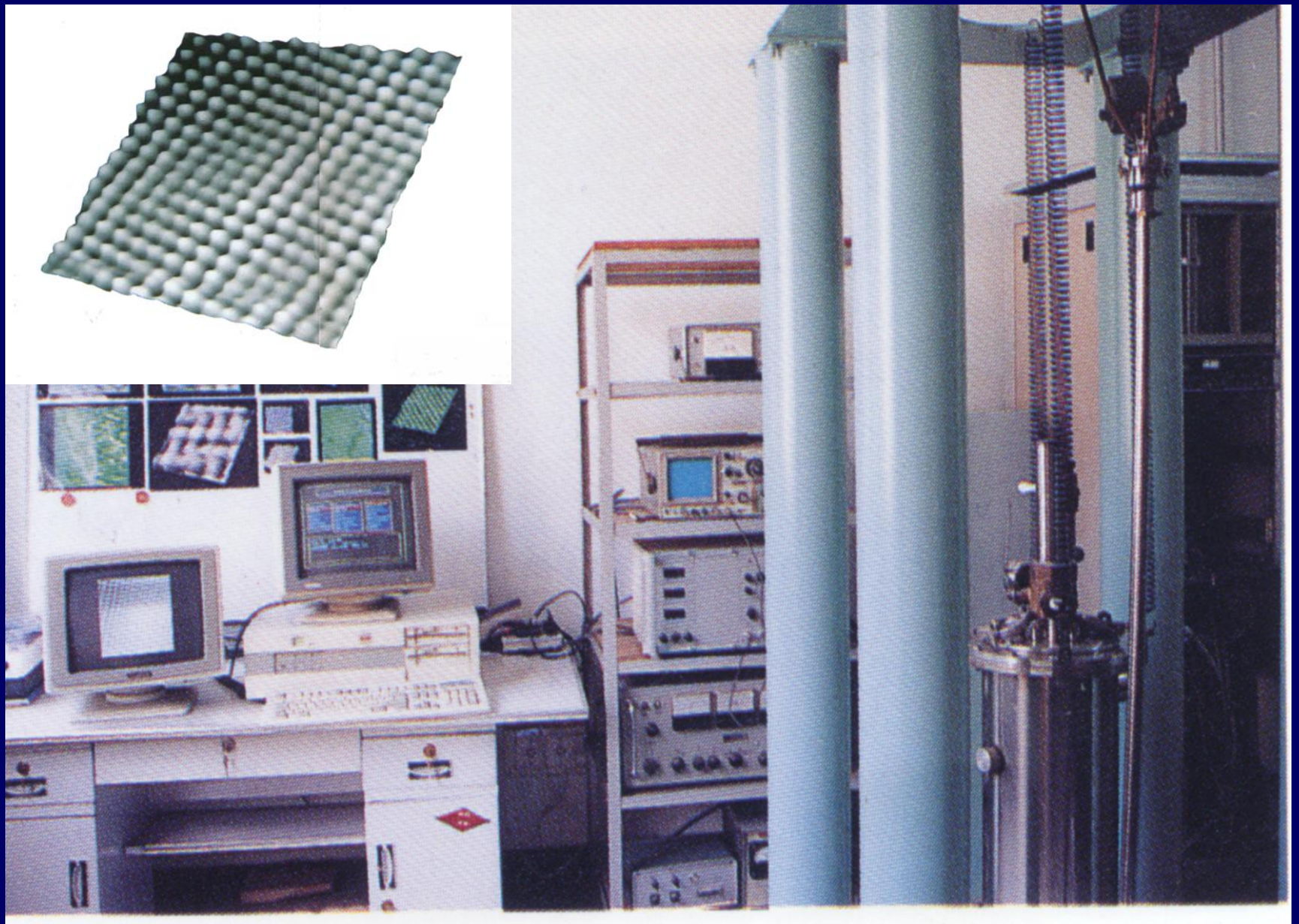






# Facilities

---

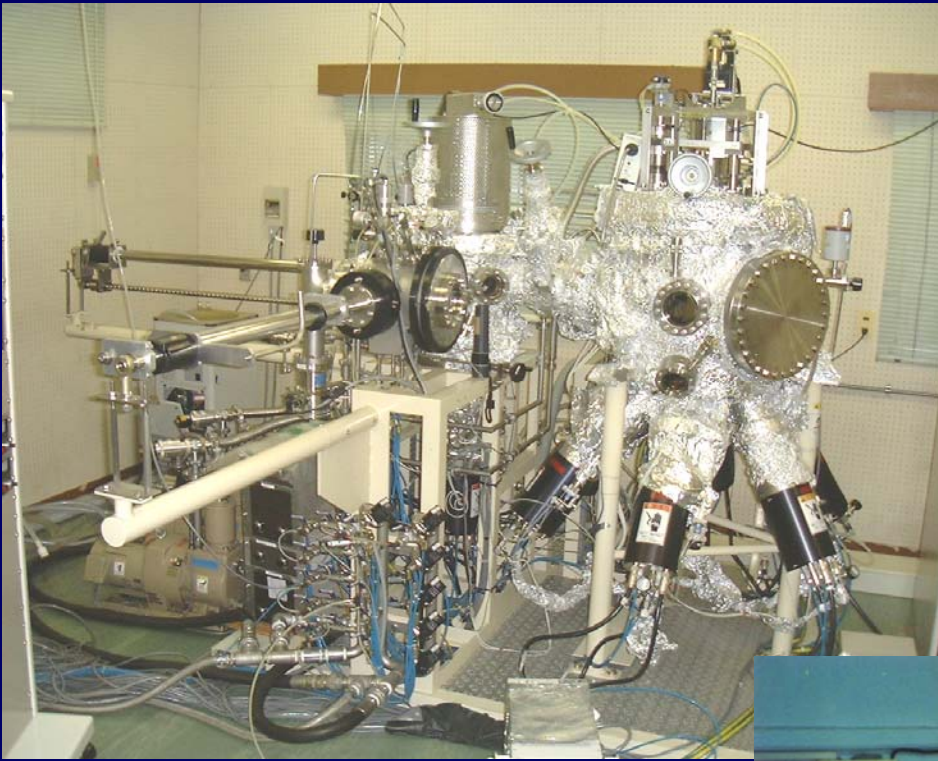


**Low temperature scanning tunneling microscopy**

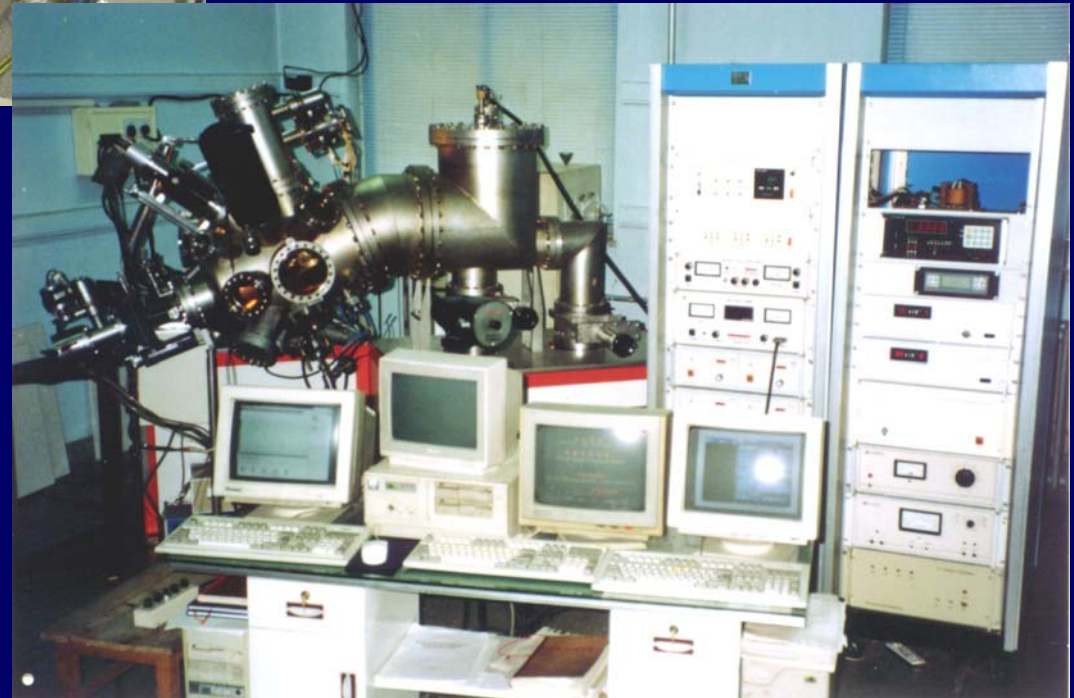


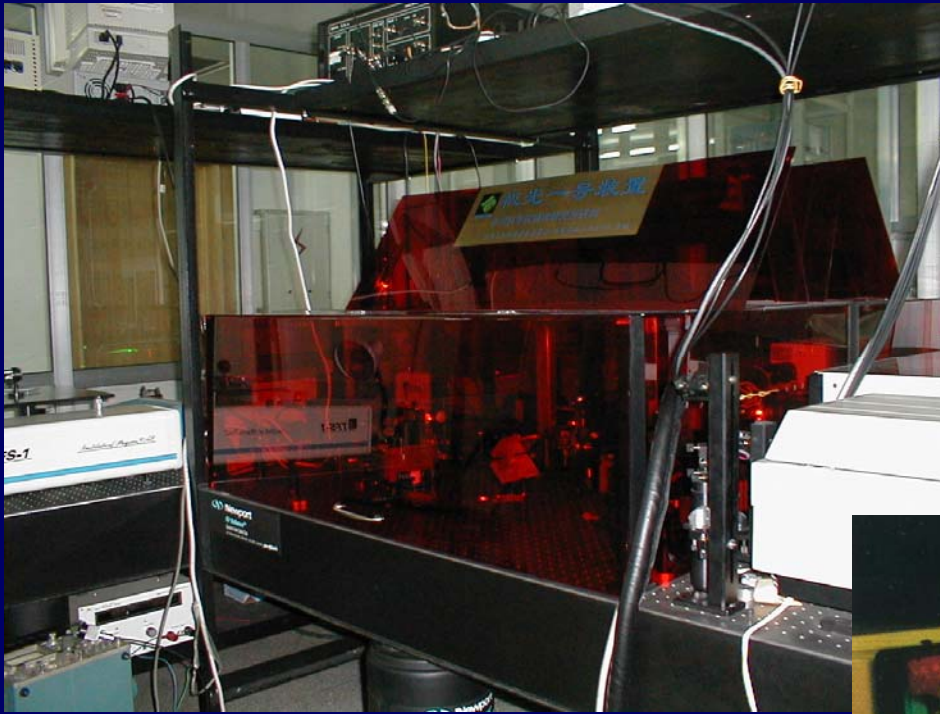


## Thin Film Deposition Systems



**Laser-molecular beam epitaxy  
system**





“Jiguang I” laser equipment



Multi-wavelength optical parametric  
laser

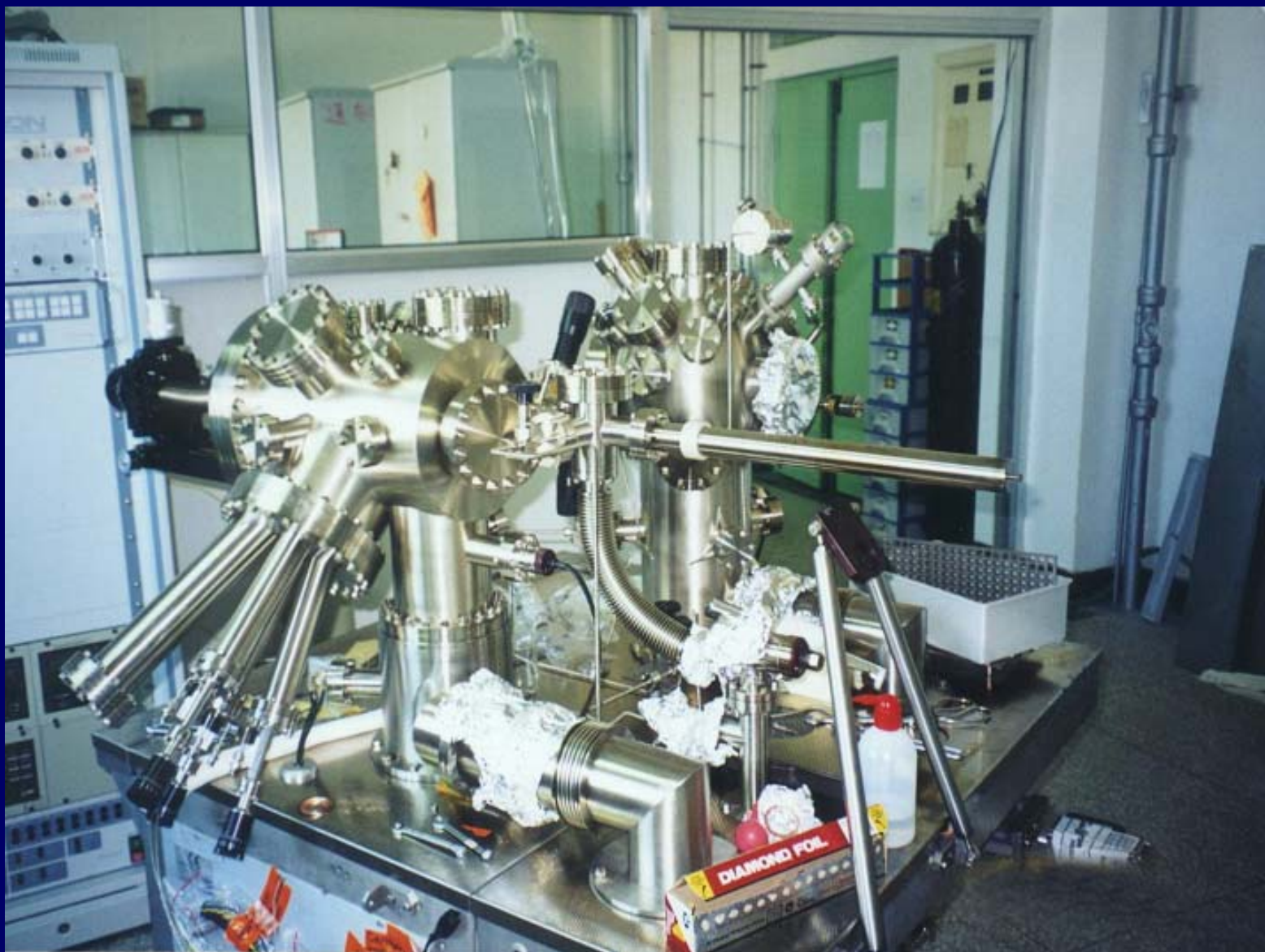




建成20TW级的  
飞秒激光装置  
聚焦功率密度  
超过 $10^{19}\text{W}/\text{cm}^2$   
成为世界上为  
数不多的可以进  
行相对论光强  
实验的装置



**640mJ/30fs, 20TW= $2 \times 10^{13}\text{W}$ , 聚焦功率密度 $>10^{19}\text{W}/\text{cm}^2$**



**Omicron temperature variable scanning tunneling microscopy  
and molecular beam epitaxy combined system**

**UHV-VT-STM-MBE**





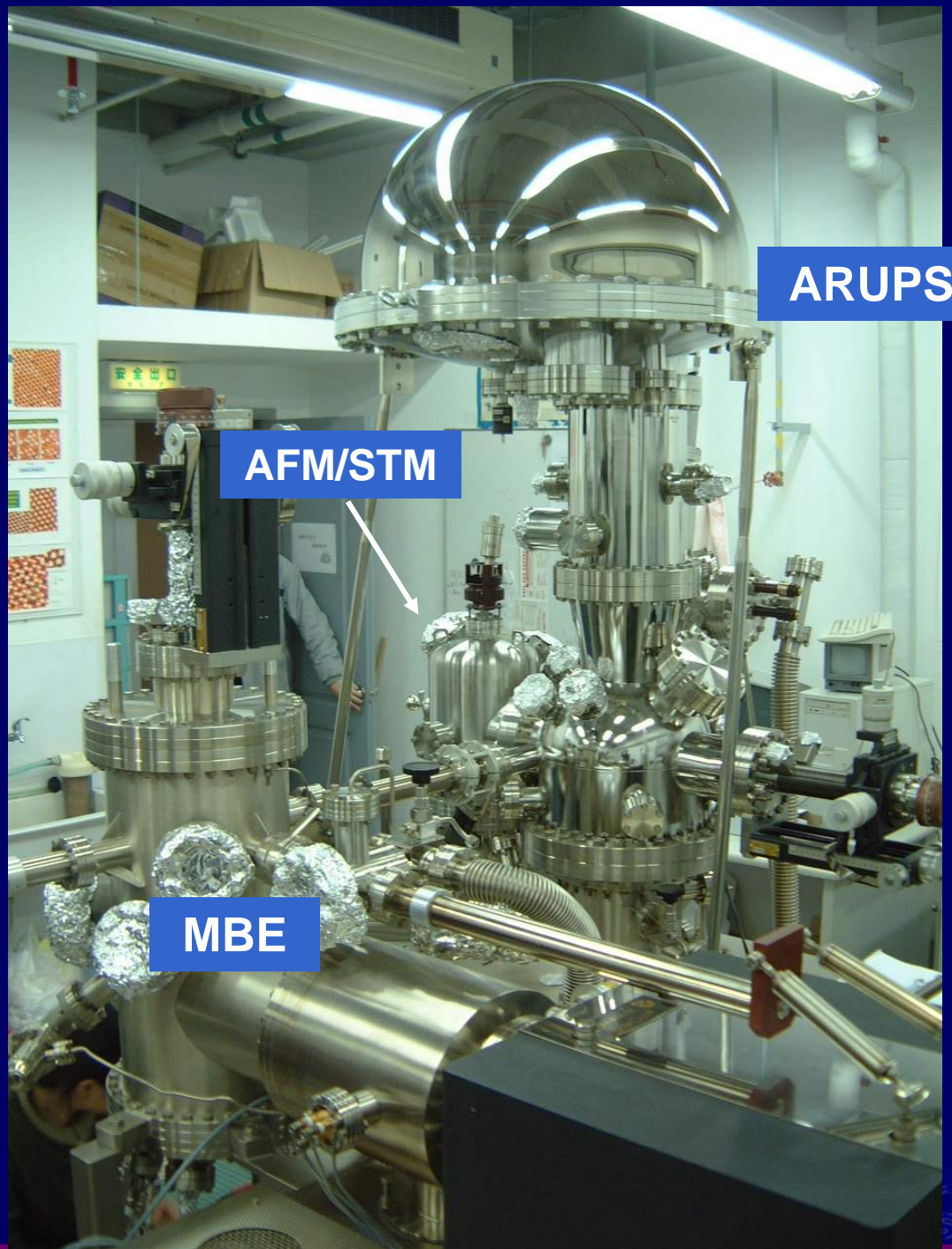
# AFM/STM-MBE- ARUPS System

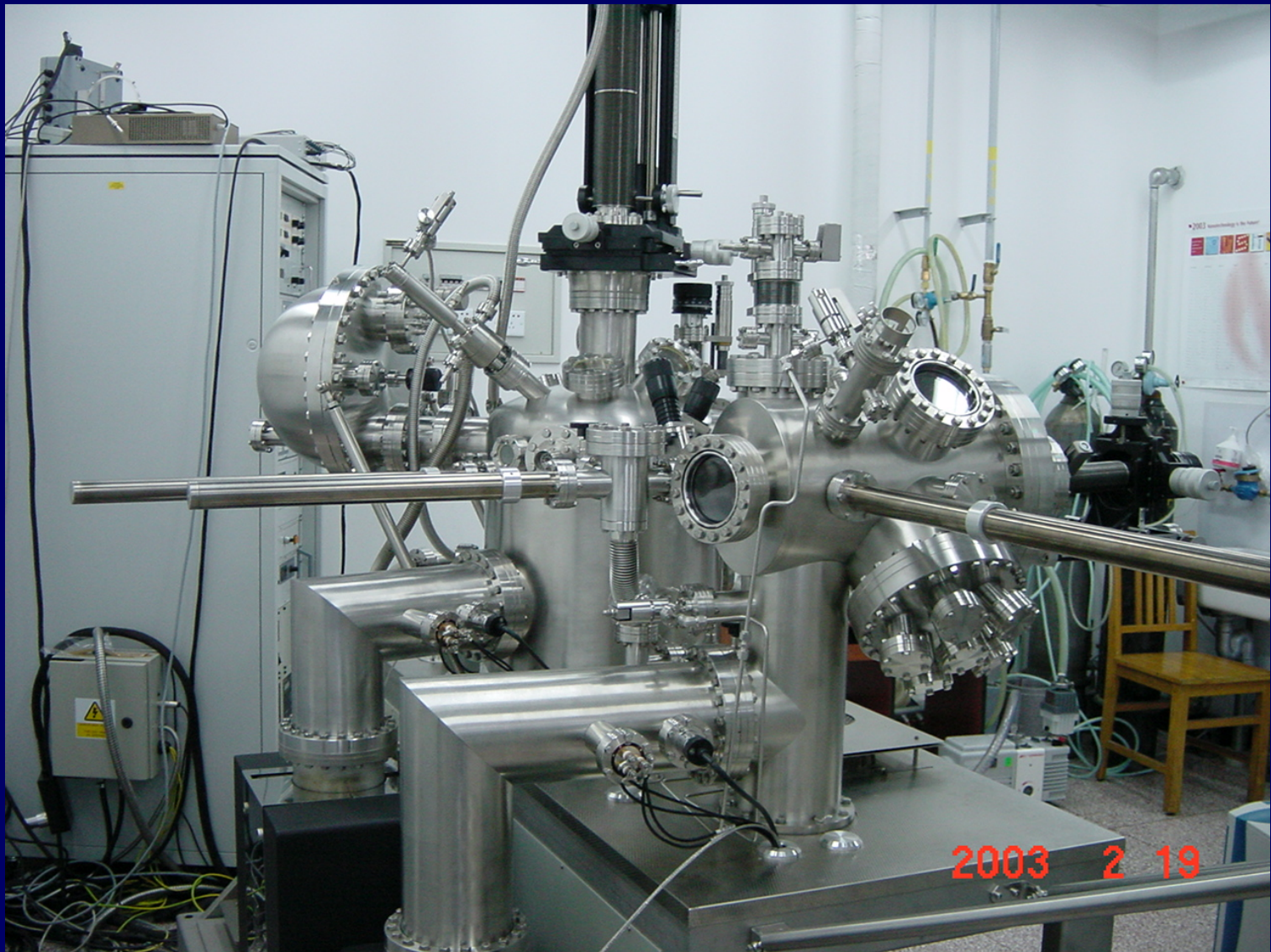
AFM: beam reflection

Temperature :

28K-1000K

能量分辨:  $< 2\text{meV}$





UHV-HREELS-UPS-STM-MBE System



# Ultra-Low Temperature – High Magnetic Field – Dual Tip UHV STM/STS system

- 1 Independent dual tip STM with position sensor;
2. The sample can be rotated continuously with respect to magnetic field;
- 3 Exchangeable dual tip STM head;
- 4 By using optical windows, magnetic-optical measurement and characterization of optical properties of nano-structures under extreme conditions can be carried out.
- 5 Transport measurement can be performed.



# Intergrated High-Resolution TEM-SPM System

The TEM is equipped with EELS and EDS, by which the microstructure, electronic structure, phononic structure and chemical composition of nano-object can be measured. The SPM has two tips for in-situ manipulations and property measurements.



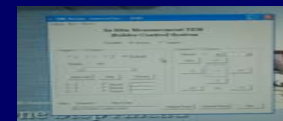
STM Mechanical Unit



STM Controller



STM Tip Manipulator



Central Processor



Physical Measurement

**Ultra-low temperatures**  
**Strong magnetic fields**  
**( 17 mK, 10 T )**





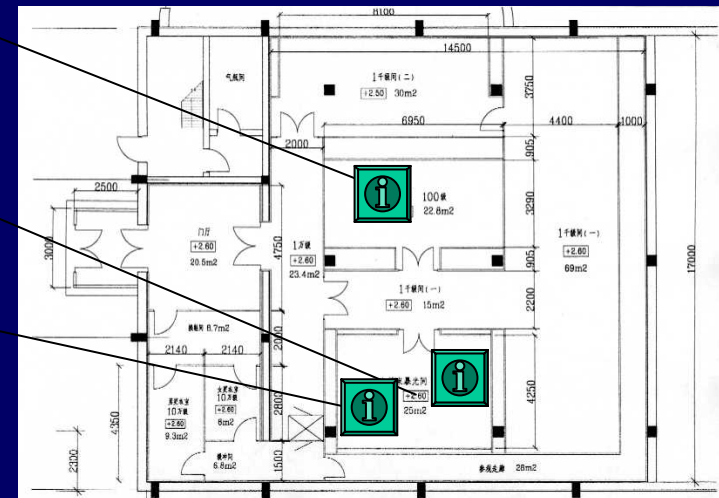
# Micro-fabrication laboratory



**Photolithography:  $< 500\text{nm}$**

**EBL System:  $< 50\text{nm}$**

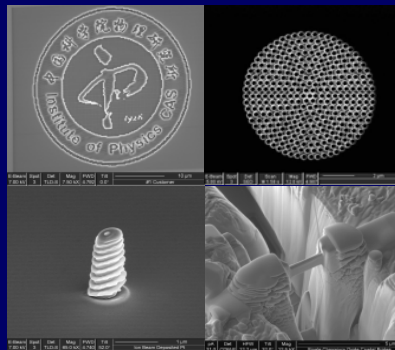
**FIB System:  $< 7\text{nm}$**



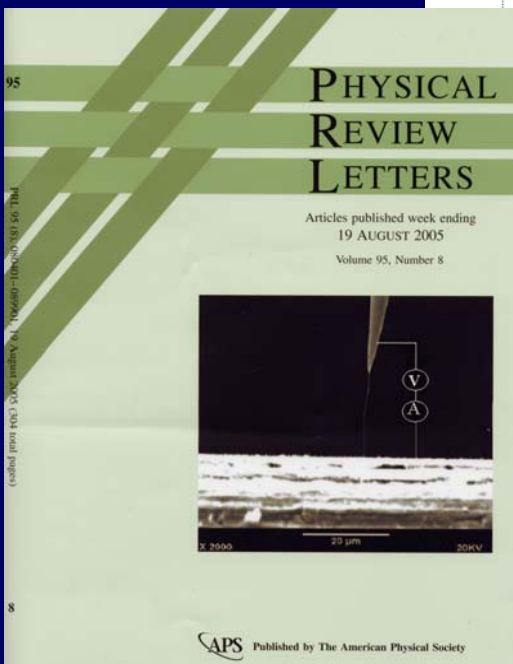
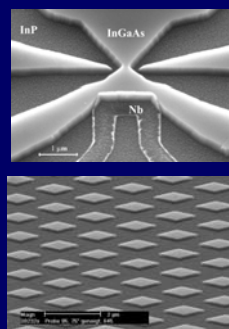
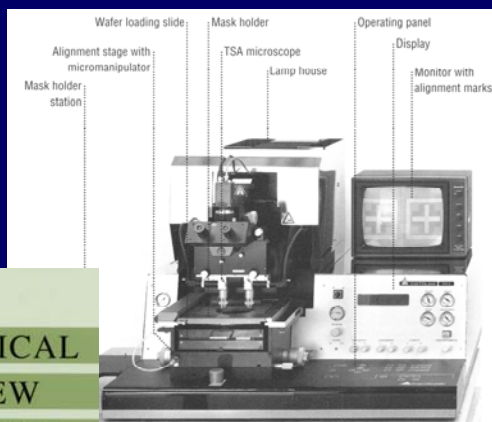




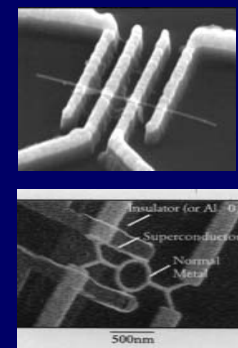
**Photolithography --- MA6**  
**DB 235M Resolution: 7 nm**



**Micro-fabrication laboratory**  
**每年举办培训班全国各地350人**

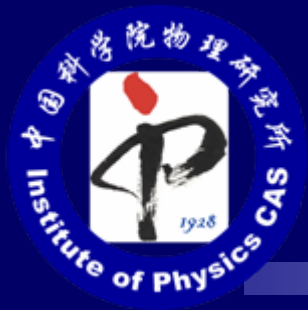


**Photolithography --- MA6**  
**Resolution: < 500 nm**



**EBL --- Raith 150**  
**Resolution: better than 50 nm**





# Campus Life

---



## Campus of the Institute





**Guest house & dinning hall**







**Conference Room and Main Hall in Building D**

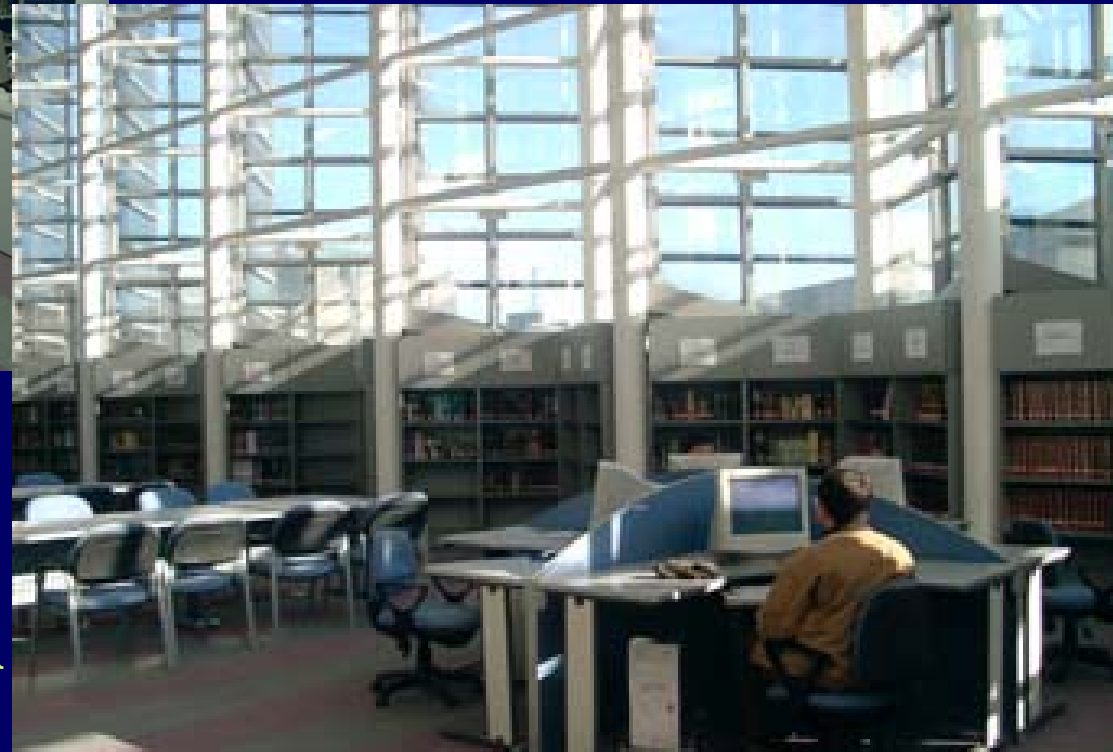
**About 250000 volumes of collection books**

**About 3000 kinds of electronic journals**

**About 1042 kinds of collection journals**

**About 200 kinds of journal subscriptions**

**Free Internet**



**library & reading room**

# The top universities in China (Physics)

( Oct. 11, 2003 By CCTV News )

| Institutes and Universities        | Standard |       |
|------------------------------------|----------|-------|
|                                    | Rank     | Mark  |
| Institute of Physics, CAS          | 1        | 96.97 |
| Peking University                  | 2        | 92.64 |
| Nanjing Univeristy                 | 3        | 90.28 |
| Chinese University of Sci. & Tech. | 4        | 88.08 |
| Fudan University                   | 5        | 85.6  |
| Institute of Optical Physics, CAS  | 5        | 85.6  |
| Tsinghua University                | 7        | 82.59 |
| Institute of Engineering Physics   | 8        | 81.37 |
| Shichuan University                | 9        | 80.95 |
| Nankai University                  | 10       | 77.26 |

# **Beijing National Lab for Condensed Matter Physics (2003-)**

**Lab for Magnetism**

**Lab for Superconductivity**

**Lab for Surface Physics**

**Lab for Optical Physics**

**Lab for Electron Microscopy**

**Lab for Nano-Physics & Nano-Technology**

**Lab for Physics in Extreme Conditions**

**Lab for Soft Matter Physics**

**Lab for Condensed Matter Theory & Materials Computation**

**Lab for Microfabrication**

**Lab for Quantum Information & Quantum Computing**

**International Center for Quantum Structure (ICQS)**

**Beijing Spallation Neutron Source (BSNS) (2005 - )**





The mission of IPCAS is to foster scientific progress by bringing together top-notch researchers in an open and stimulating environment.





[WWW.IPHY.AC.CN](http://WWW.IPHY.AC.CN)